

ORIGINAL

Application Based on

Docket **87610AEK**

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Customer No. 01333

**ELECTROLUMINESCENT DEVICE WITH ANTHRACENE
DERIVATIVE HOST**

Commissioner for Patents,
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Express Mail Label No.: EV293530162US

Date: March 25, 2004

ELECTROLUMINESCENT DEVICE WITH ANTHRACENE
DERIVATIVE HOST

FIELD OF INVENTION

5 This invention relates to organic electroluminescent (EL) devices comprising a light-emitting layer containing a host and a light-emitting material where the host comprises a particular anthracene compound with good operational stability.

BACKGROUND OF THE INVENTION

10 While organic electroluminescent (EL) devices have been known for over two decades, their performance limitations have represented a barrier to many desirable applications. In simplest form, an organic EL device is comprised of an anode for hole injection, a cathode for electron injection, and an organic
15 medium sandwiched between these electrodes to support charge recombination that yields emission of light. These devices are also commonly referred to as organic light-emitting diodes, or OLEDs. Representative of earlier organic EL devices are Gurnee et al. US 3,172,862, issued Mar. 9, 1965; Gurnee US
3,173,050, issued Mar. 9, 1965; Dresner, "Double Injection Electroluminescence
20 in Anthracene", *RCA Review*, 30, 322-334, (1969); and Dresner US 3,710,167, issued Jan. 9, 1973. The organic layers in these devices, usually composed of a polycyclic aromatic hydrocarbon, were very thick (much greater than 1 μm). Consequently, operating voltages were very high, often greater than 100V.

 More recent organic EL devices include an organic EL element
25 consisting of extremely thin layers (e.g., less than 1.0 μm) between the anode and the cathode. Herein, the term "organic EL element" encompasses the layers between the anode and cathode. Reducing the thickness lowered the resistance of the organic layer and has enabled devices that operate at much lower voltage. In a basic two-layer EL device structure, described first in US 4,356,429, one organic
30 layer of the EL element adjacent to the anode is specifically chosen to transport holes, and therefore, it is referred to as the hole-transporting layer, and the other

organic layer is specifically chosen to transport electrons, and is referred to as the electron-transporting layer. Recombination of the injected holes and electrons within the organic EL element results in efficient electroluminescence.

There have also been proposed three-layer organic EL devices that
5 contain an organic light-emitting layer (LEL) between the hole-transporting layer and electron-transporting layer, such as that disclosed by Tang et al (*J. Applied Physics*, **65**, Pages 3610-3616, (1989)). The light-emitting layer commonly consists of a host material doped with a guest material, also known as a dopant. Still further, there has been proposed in US 4,769,292 a four-layer EL element
10 comprising a hole-injecting layer (HIL), a hole-transporting layer (HTL), a light-emitting layer (LEL) and an electron transport/injection layer (ETL). These structures have resulted in improved device efficiency.

Since these early inventions, further improvements in device materials have resulted in improved performance in attributes such as color,
15 stability, luminance efficiency and manufacturability, e.g., as disclosed in US 5,061,569, US 5,409,783, US 5,554,450, US 5,593,788, US 5,683,823, US 5,908,581, US 5,928,802, US 6,020,078, and US 6,208,077, amongst others.

Anthracene based hosts are often used in EL devices. A useful class of 9,10-di-(2-naphthyl)anthracene hosts has been disclosed in US 5,935,721.
20 Bis-anthracene compounds used in the luminescent layer with an improved device half-life have been disclosed in US 6,534,199 and US 2002/0136922. Electroluminescent devices with improved luminance using anthracene compound have been disclosed in US 6,582,837. Anthracenes have also been used in the HTL as disclosed in US 6,465,115. In addition there are other disclosures of using
25 anthracene materials in EL devices, US 5,972,247, JP 2001/097897, JP 2000/273056, US 2002/0048687, WO 2003/060956, WO 2002/088274, WO 2003/087023 EP 0429821, WO 2003/007658, JP 2000/053677, and JP 2001/335516.

K. Kim and coworkers (US 2004/0023060) describe double spiro
30 anthracene derivatives. Among the materials reported are those which have a double spiro group located in the 2-positions of a 9,10 substituted anthracene,

although materials of this nature may have a large number of carbocyclic rings and may have a high sublimation temperature.

S Yoon and coworkers, WO 2003/060956, describe anthracene materials in which one to two imidazole groups are located in the 2 or 2,6-positions of 9,10 substituted anthracenes. JP 2004/059535 describes anthracene materials in which aryl and heteroaryl groups are located the 2- or 2,6-positions of 9,10 substituted anthracenes. However, anthracenes substituted in such positions may be difficult and expensive to manufacture and may not provide all the desirable embodiments of a host material.

Despite these advances, there is a continuing need for hosts that provide high luminance yield and have improved operational stability, desirable hue, and that are conveniently manufactured.

SUMMARY OF THE INVENTION

The invention provides an electroluminescent device comprising a light emitting layer including an anthracene material bearing at least one aryl ring in the 2-position and having a hydrogen or an alkyl group in the 6-position and having up to 12 aromatic carbocyclic rings including at least one naphthalene group in the 9-position of the anthracene group and an aryl group in the 10-position, the anthracene material including among the rings only carbocyclic rings. The invention also includes the anthracene compound as well as a display, a lighting device, and a process employing the electroluminescent device

Embodiments of the invention provide high luminance yield, have improved operational stability and a desirable hue and that are conveniently manufactured.

BRIEF DESCRIPTION OF THE DRAWINGS

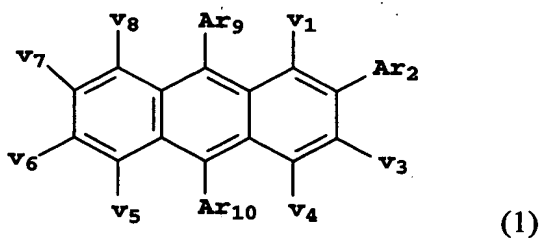
Figure 1 shows a cross-section of a typical OLED device in which this invention may be used.

DETAILED DESCRIPTION OF THE INVENTION

The invention is generally summarized above. In one embodiment an electroluminescent device of the invention is a multilayer device comprising a cathode, an anode, charge-injecting layers (if necessary), charge-transporting
5 layers, and at least one light-emitting layer (LEL) comprising a host and at least one light-emitting material.

The device includes a layer containing an anthracene material bearing at least one aryl ring in the 2-position, for example, a phenyl group, a naphthyl group or a biphenyl group. The anthracene material also bears a
10 hydrogen or alkyl group, such as a methyl or *t*-butyl, group in the 6-position. The anthracene material comprises up to 12 aromatic carbocyclic rings and including among the rings only carbocyclic rings. In one desirable embodiment the anthracene comprises up to 10 aromatic carbocyclic rings. The anthracene material includes at least one naphthalene group in the 9-position of the
15 anthracene. In one suitable embodiment the naphthalene group is a 2-naphthyl group. The 10-position of the anthracene is aryl substituted. In one embodiment the aryl substituent is a naphthyl group, such as a 2-naphthyl group or a biphenyl group, such as a 4-biphenyl group. In one desirable embodiment the 9- and 10-positions are substituted with the same naphthyl group. Suitably the anthracene
20 material comprises only one anthracene moiety, that is, there is only one anthracene group present in the compound. In another embodiment the anthracene material comprises only two anthracene moieties, that is, there are two independently selected anthracene groups present in the compound.

In one embodiment, the anthracene material is represented by
25 Formula (1),



In Formula (1), Ar₂ represents an aryl group, such as a phenyl group, a naphthyl group or a biphenyl group. Ar₉ represents a naphthyl group, such as a 2-naphthyl group or a 1-naphthyl group. Ar₁₀ represents an aryl group. Examples of aryl groups are phenyl groups, tolyl groups, naphthyl groups and
5 biphenyl groups. In Formula (1), v₁, v₃, v₄, v₅, v₇, and v₈ independently represent hydrogen or an independently selected substituent group, such as an aryl group, for example a phenyl group, or an alkyl groups such as a *t*-butyl group. In Formula (1), v₆ represents hydrogen or an alkyl group, such as a *t*-butyl group.

Desirably the anthracene material is in a layer that includes a light
10 emitting material. Suitably, the anthracene material comprises the host material, and there may be more than one host materials. The light-emitting material(s) is present in an amount of up to 15 vol. % of the host, commonly 0.1 – 10 vol. % and more typically from 0.1-5.0 vol. % of the host.

The anthracene material may also be part of an oligomer or a
15 polymer having a main chain or a side chain of repeating units. In one useful embodiment, at least one layer of the EL device, comprises polymeric material. In another suitable embodiment, at least two layers of the EL device comprise polymeric material.

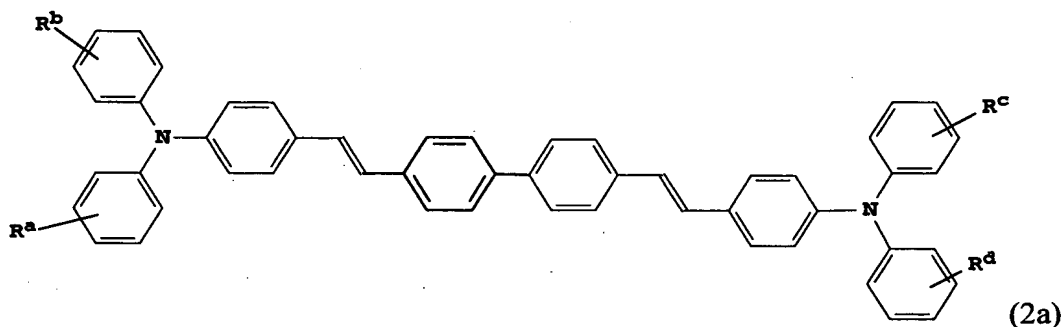
An important relationship for choosing a light-emitting fluorescent
20 material for use with a host is a comparison of the excited singlet-state energies of the host and the fluorescent material. It is highly desirable that the excited singlet-state energy of the light-emitting material be lower than that of the host material. The excited singlet-state energy is defined as the difference in energy between the emitting singlet state and the ground state. For non-emissive hosts, the lowest
25 excited state of the same electronic spin as the ground state is considered the emitting state.

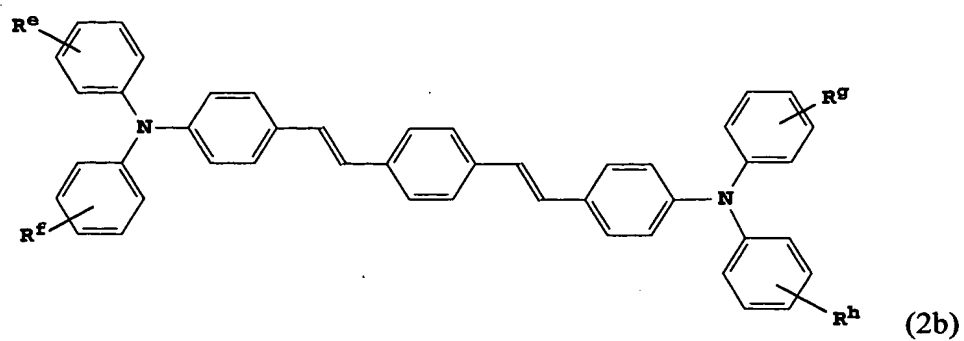
The layer may emit light ranging from blue to red depending on the nature of the light-emitting material. Blue light is generally defined as having a wavelength range in the visible region of the electromagnetic spectrum of 450-480
30 nm, blue-green 480-510 nm, green 510-550, green-yellow 550-570 nm, yellow 570-590 nm, orange 590-630 nm and red 630-700 nm, as defined by R. W. Hunt,

The Reproduction of Colour in Photography, Printing & Television, 4th Edition
1987, Fountain Press. Suitable combinations of these components produce white
light. When light has a spectral profile that overlaps these ranges, to whatever
degree, it is loosely referred to as having both color components for example,
5 blue-green, yellow-orange or orange-red.

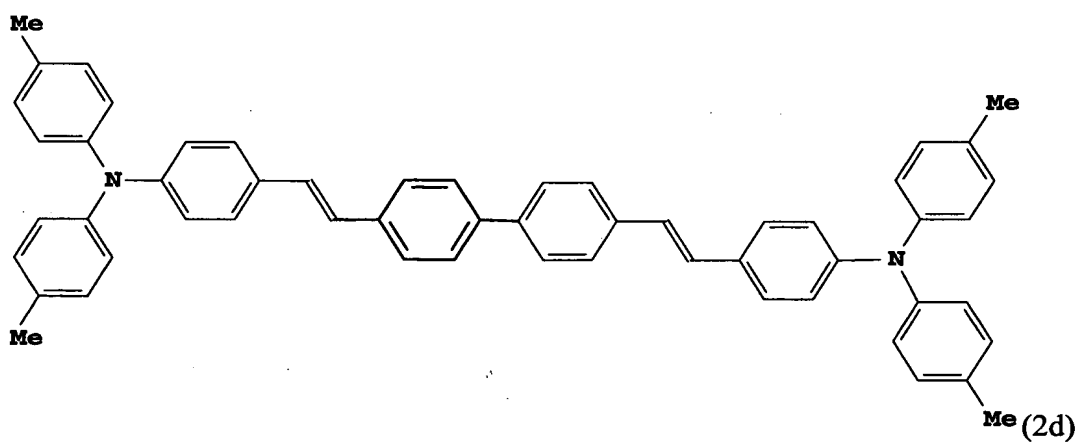
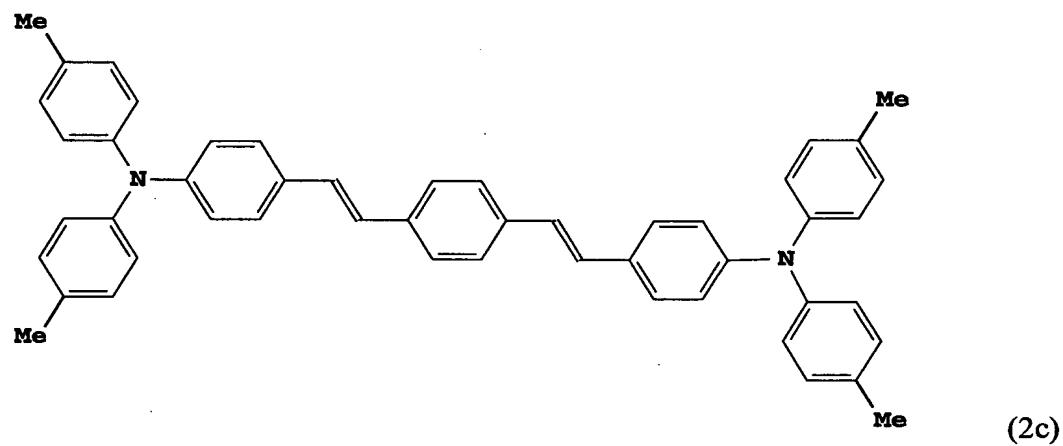
Anthracene materials of the invention may be especially useful
hosts for blue or blue-green materials. Many materials that emit blue or blue-
green light are known in the art and are contemplated for use in the practice of the
present invention. Particularly useful classes of blue emitters include perylene and
10 its derivatives such as a perylene nucleus bearing one or more substituents such as
an alkyl group or an aryl group. A desirable perylene derivative for use as an
emitting material is 2,5,8,11-tetra-*t*-butylperylene.

Another useful class of fluorescent materials includes blue or blue-
green light emitting derivatives of distyrylarenes, such as distyrylbenzene and
15 distyrylbiphenyl, including compounds described in US 5,121,029. Among
derivatives of distyrylarenes that provide blue or blue-green luminescence,
particularly useful are those substituted with diarylamino groups, also known as
distyrylamines. Examples include Formula 2a and 2b, listed below, wherein R^a –
R^h can be the same or different, and individually represent hydrogen or one or
20 more substituents. For example, substituents can be alkyl groups, such as methyl
groups, or aryl groups, such as phenyl groups.



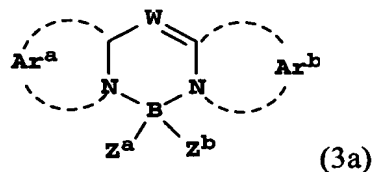


Illustrative examples of useful distyrylamines are blue or blue green emitters, (2c) and (2d) listed below.



Another useful class of blue or blue green emitters comprise a boron atom. Desirable light-emitting materials that contain boron include those

described in US 2003/0198829 and US 2003/0201415. Suitable blue or blue-green light-emitting materials are represented by the structure Formula (3a).



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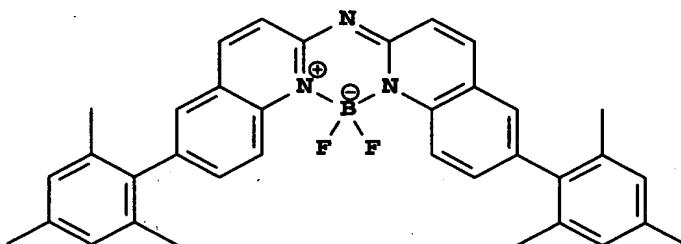
In Formula (3a), Ar^a and Ar^b independently represent the atoms necessary to form a five or six-membered aromatic ring group, such as a pyridine group. Z^a and Z^b represent independently selected substituents, such as fluoro substituents. In Formula (3a), w represents N or C-Y, wherein Y represents hydrogen or a substituent, such as an aromatic group, such as a phenyl group or a tolyl group, an alkyl group, such as a methyl group, a cyano substituent, or a trifluoromethyl substituent.

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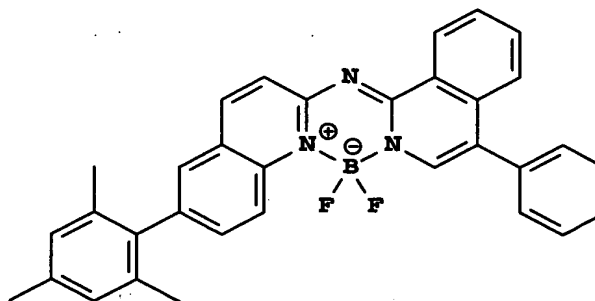
Illustrative examples of useful boron-containing fluorescent materials are listed below.

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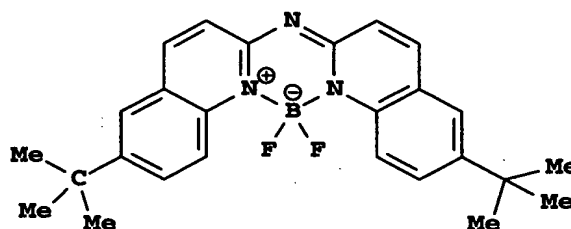
3b



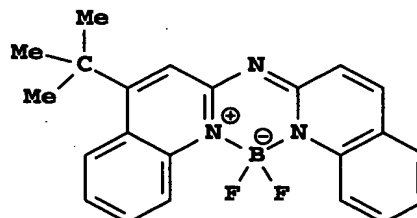
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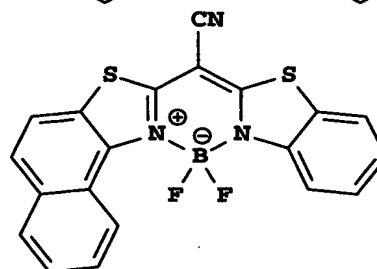
3d



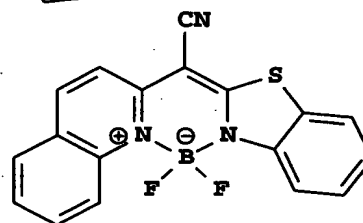
3e



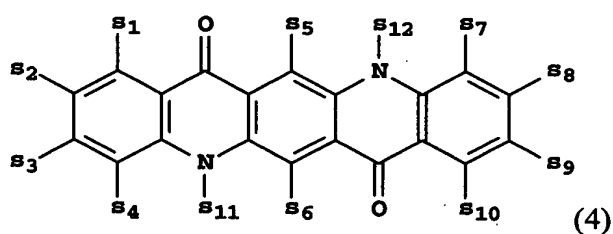
3f



3g



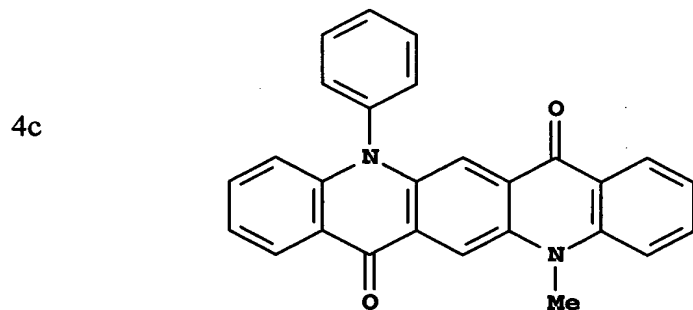
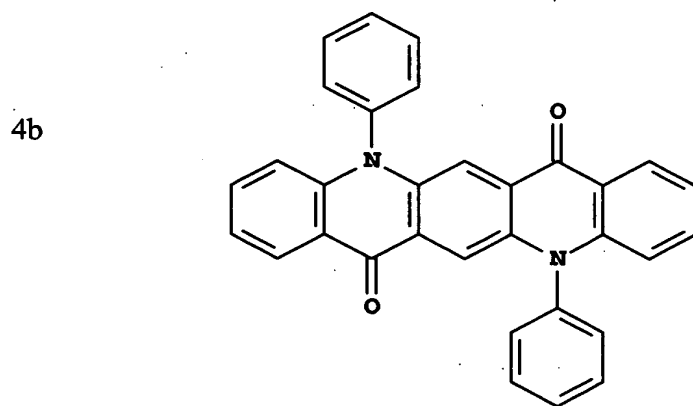
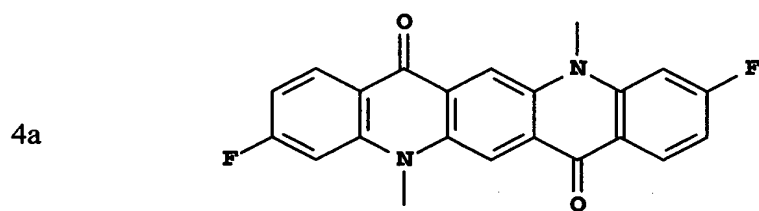
A particularly useful class of green light-emitting material includes quinacridone compounds. Useful quinacridones are described US 2004/0001969, US 6,664,396, US 5,593,788, and JP 09-13026. In one embodiment, the light-emitting material in the light-emitting layer is a quinacridone compound represented by Formula (4).



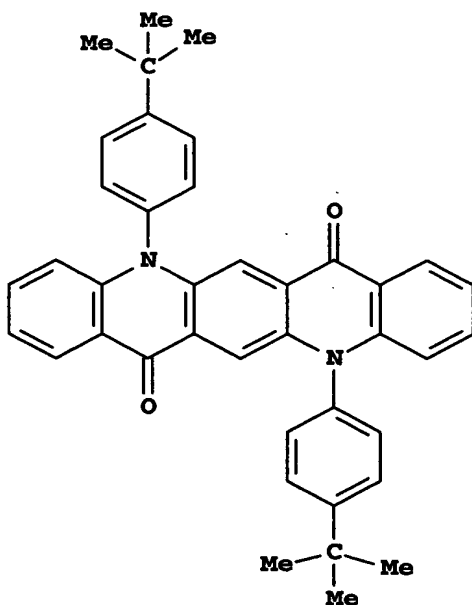
In Formula (4), s_1 – s_{10} independently represent hydrogen or an independently selected substituent, such as a phenyl group, a tolyl group, a halogen such as F, or an alkyl group, such as a methyl group. Adjacent substituents may combine to form rings, such as fused benzene ring groups.

- 5 In Formula (4), s_{11} and s_{12} independently represent an alkyl group or an aromatic group. In one suitable embodiment, s_{11} and s_{12} independently represent a phenyl ring group, such as a phenyl ring or a tolyl ring.

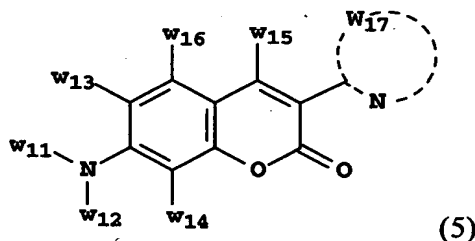
Illustrative examples of useful quinacridone compounds are shown below.



4d

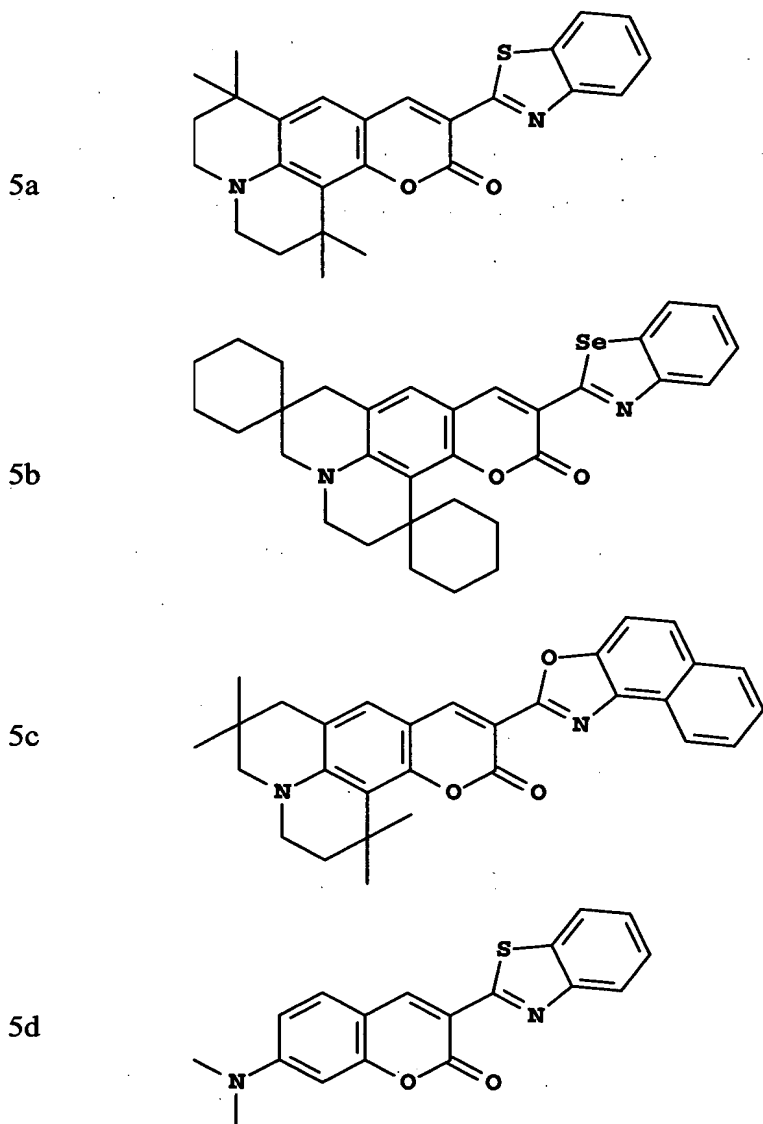


Another particularly useful class of green light-emitting materials includes coumarin compounds. For example, useful coumarins are described in Tang et al., US 4,769,292 and US 6,020,078. In one embodiment of the invention, the third material in the light-emitting layer is a coumarin represented by Formula (5).



In Formula (5), w_{11} and w_{12} represent an independently selected substituent, such as an alkyl group or aryl group, provided w_{11} and w_{12} may combine with each other or with w_{13} and w_{14} to form rings. Desirably w_{11} and w_{12} represent independently selected alkyl groups, provided w_{11} and w_{12} may combine with each other or with w_{13} and w_{14} to form saturated rings. In Formula (5), w_{13} – w_{16} independently represent hydrogen or an independently selected substituent, such as phenyl ring group or a methyl group. Adjacent substituents may combine

to form rings, such as fused benzene rings. In Formula (5), w₁₇ represents the atoms necessary to complete a heteroaromatic ring, such as a benzothiazole ring group. Illustrative examples of useful coumarin compounds are shown below.



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Examples of additional useful emitting materials include derivatives of anthracene, fluorene, periflanthene, and indenoperylene.

Anthracenes employed in the invention are useful in EL devices that exhibit high efficiencies and good operating stability. These compounds are

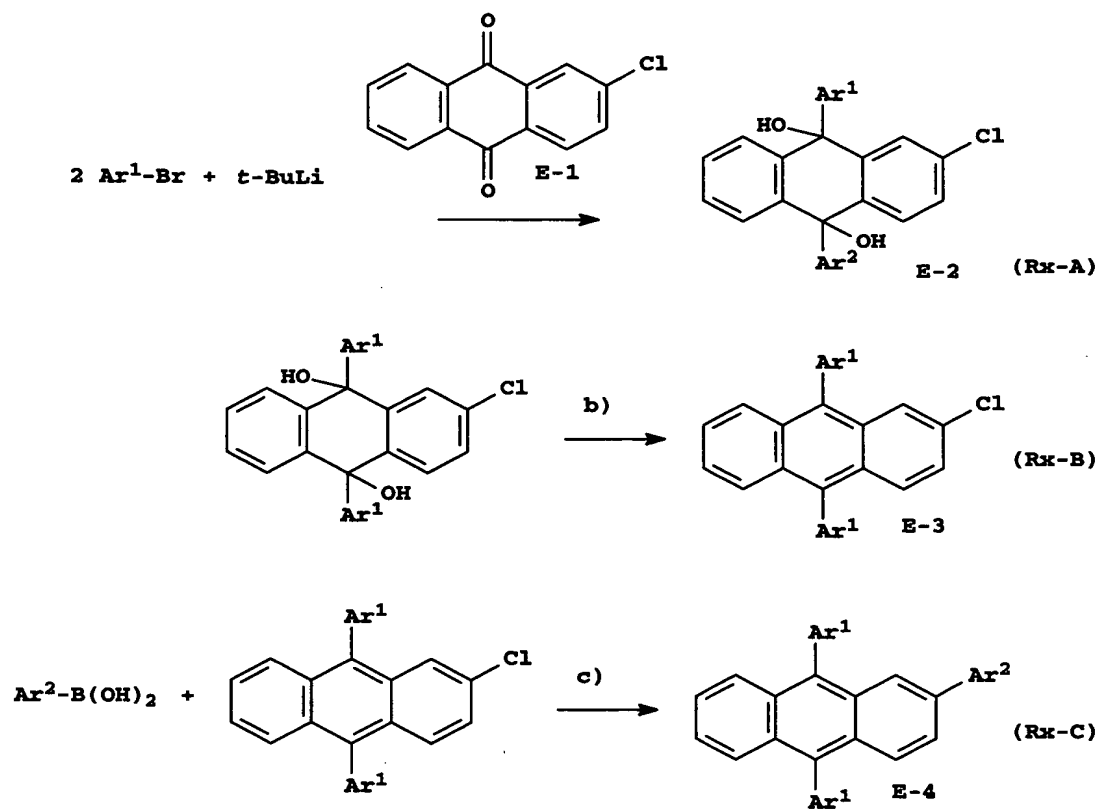
useful in EL devices that produce white light as well as in full color EL devices and motion imaging devices.

In one desirable embodiment, the device of the invention has more than one layer that emits light. Suitably the device produces white light.

- 5 Desirably, one layer of the device contains rubrene or a derivative of rubrene.

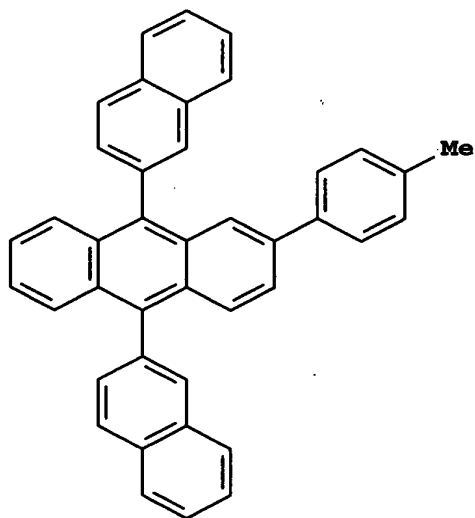
Useful anthracene materials may be made by various methods. For example, by the method shown in the reaction steps Rx-A through Rx-C.

- Reaction of a bromo-aryl compound (Ar^1Br) with a lithium reagent, for example *t*-butyllithium, forms the aryl-lithium salt, which then can react with compound E-1,
10 to form E-2 (Rx-A). Dehydration of E-2 and aromatization with, for example, KI, NaH_2PO_2 , and acetic acid, affords the anthracene E-3 (Rx-B). Reaction of this anthracene with an aryl boronic acid ($\text{Ar}^2\text{-B(OH)}_2$) under Suzuki-type coupling conditions, for example, with tris(dibenzylideneacetone)dipalladium, tricyclohexylphosphine, and potassium phosphate base, affords the desired
15 anthracene material, E-4 (Rx-C). See J. Hassan, M. Sevignon, C. Gozzi, E. Schulz, M. Lemaire, Marc, *Chem. Rev.*, **102**, 1359 (2002) and references cited therein for a review of the Suzuki coupling reaction and similar reactions.

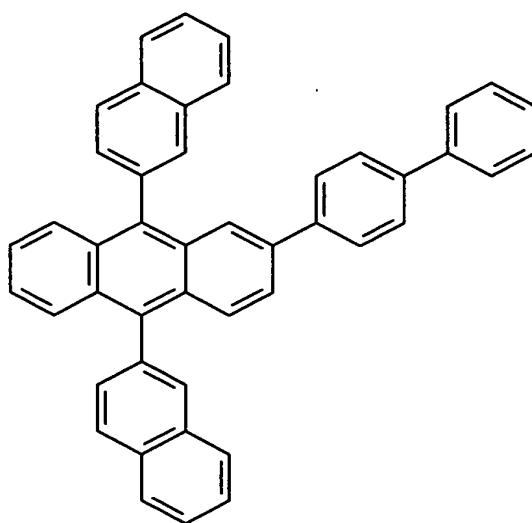


Useful compounds of this invention include:

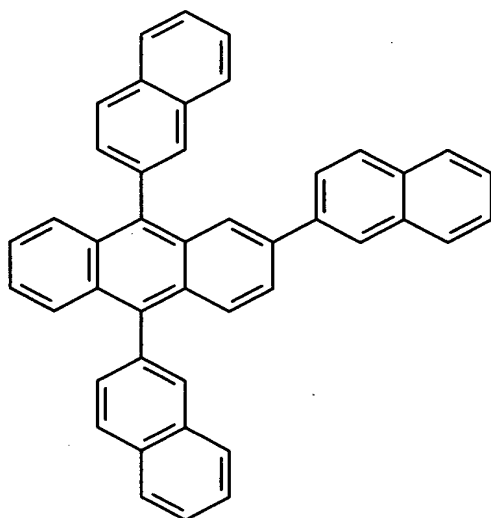
Inv-1



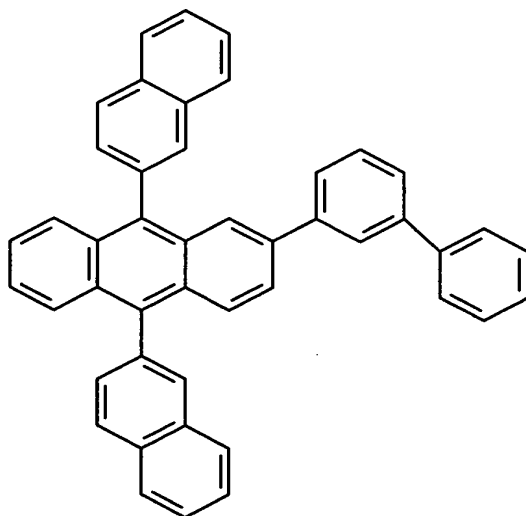
Inv-2



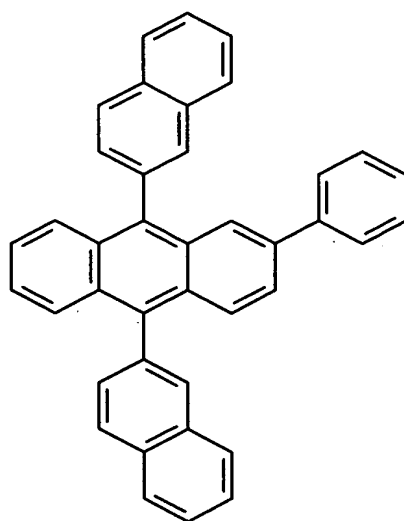
Inv-3



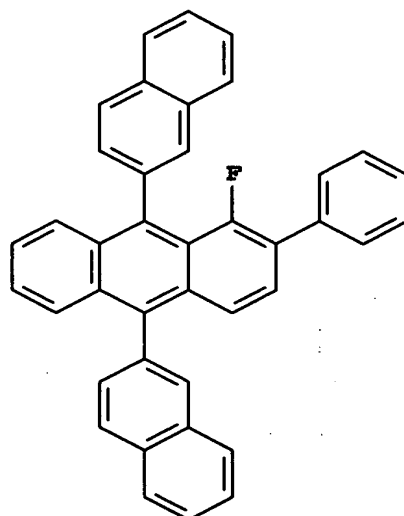
Inv-4



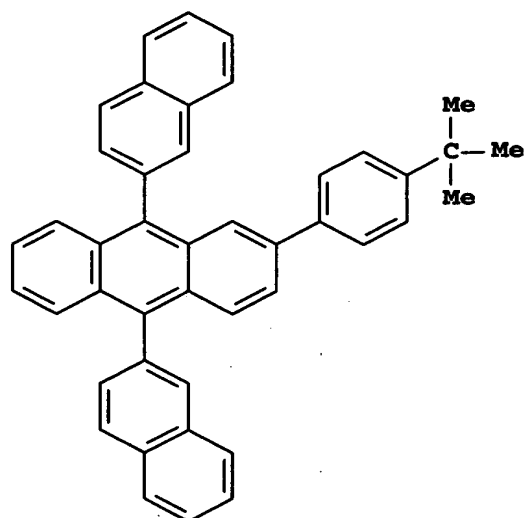
Inv-5



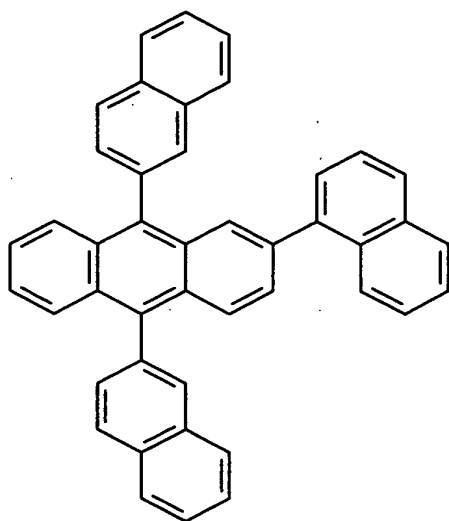
Inv-6



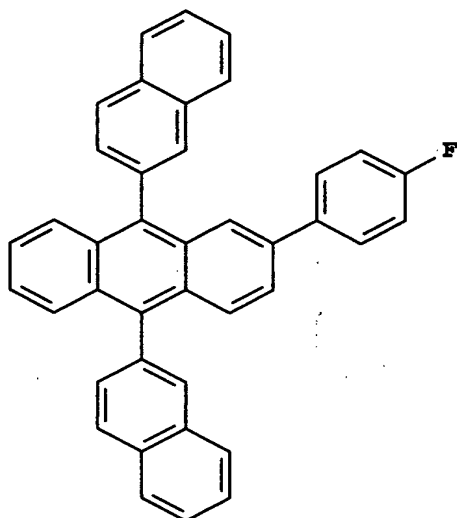
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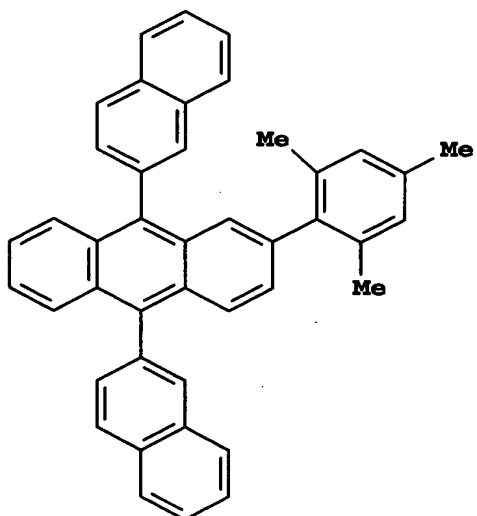
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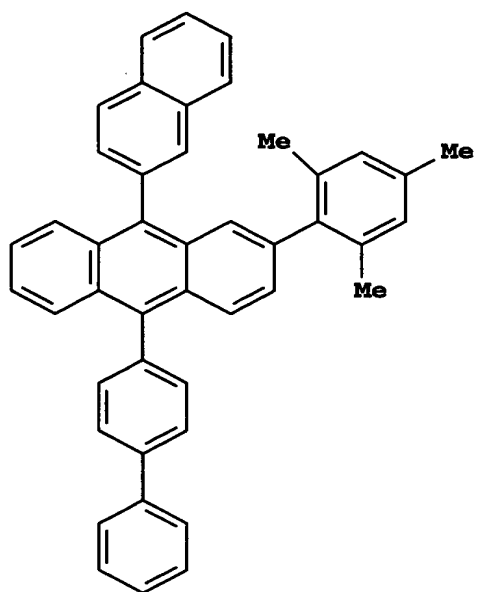
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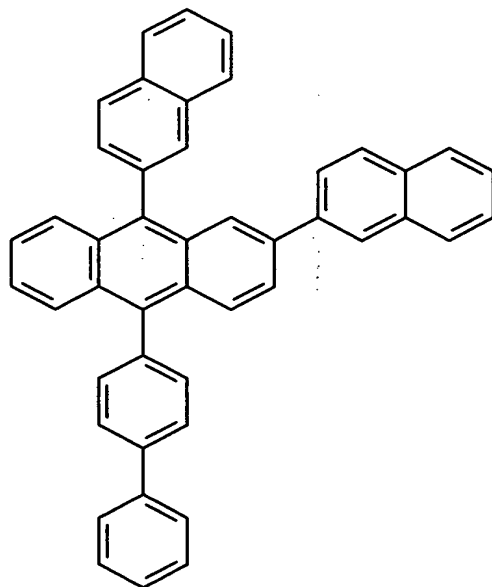
Inv-10



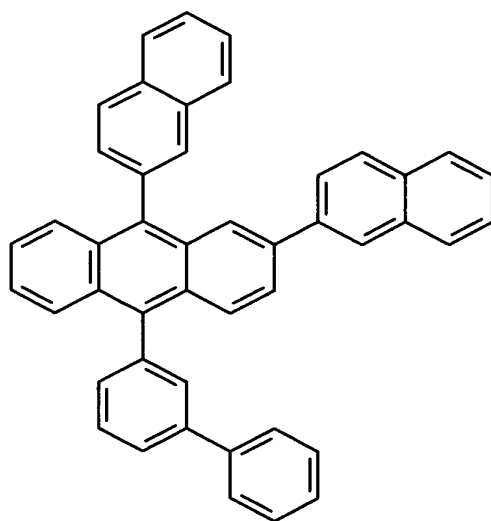
Inv-11



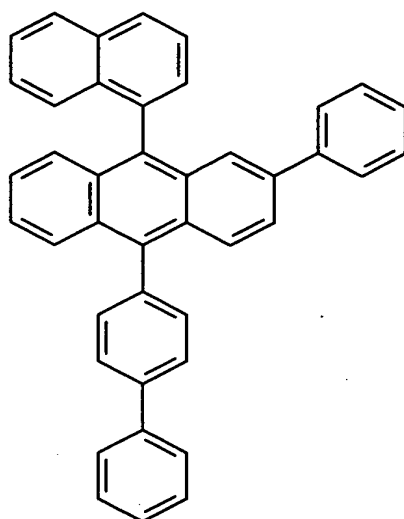
Inv-12



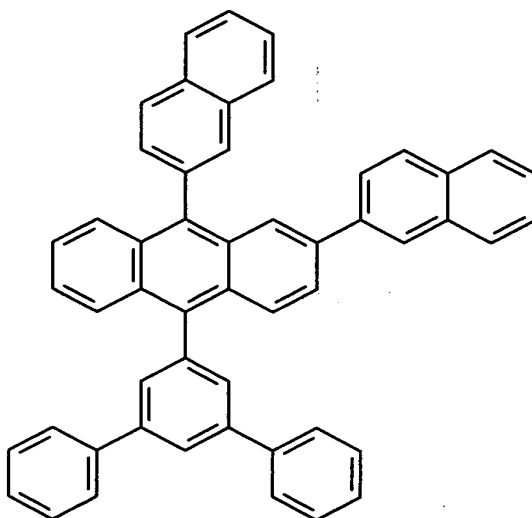
Inv-13



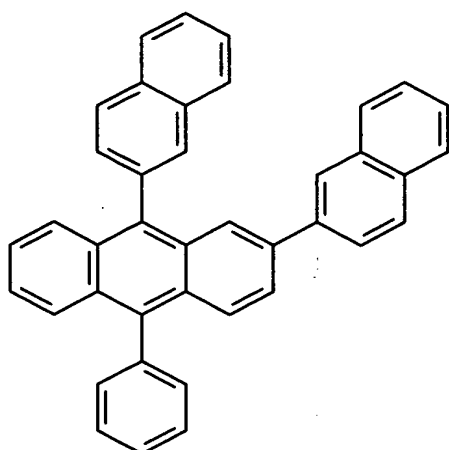
Inv-14



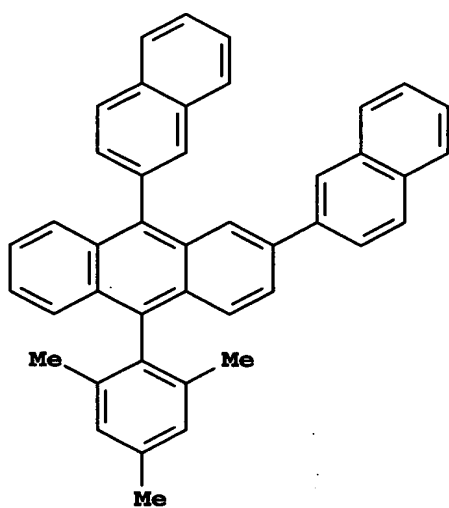
Inv-15



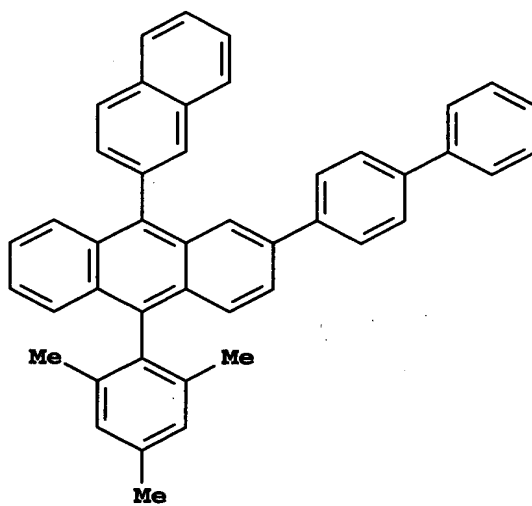
Inv-16



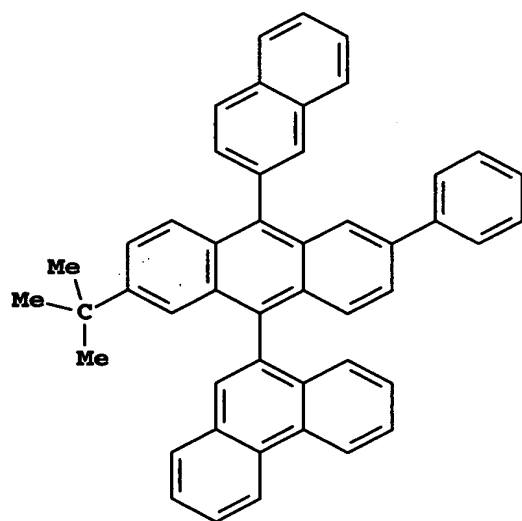
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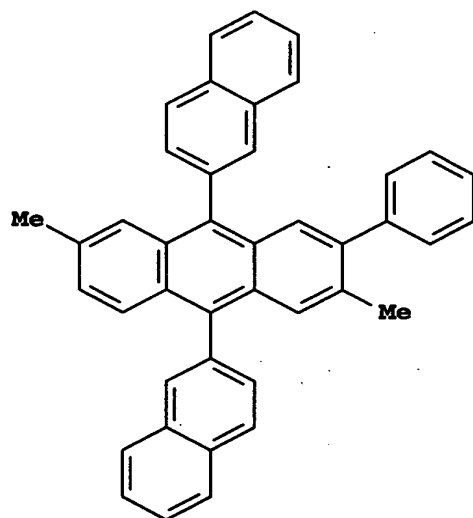
Inv-18



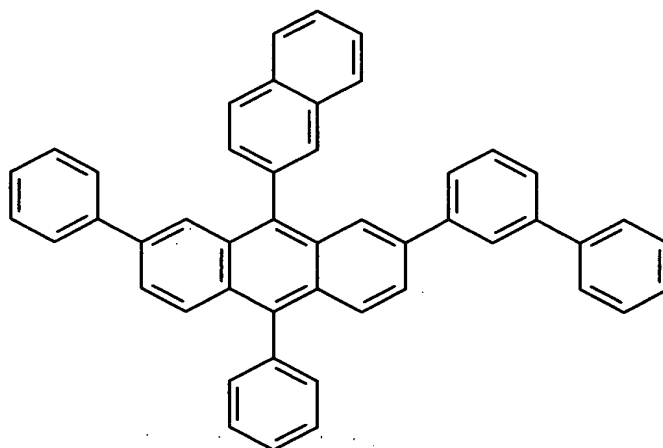
Inv-19

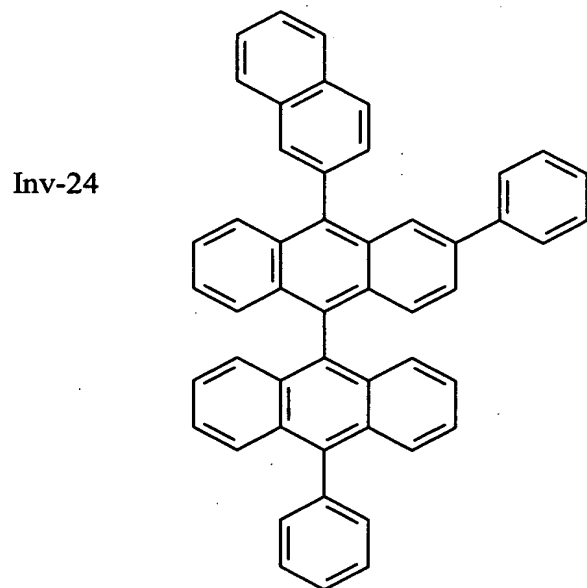
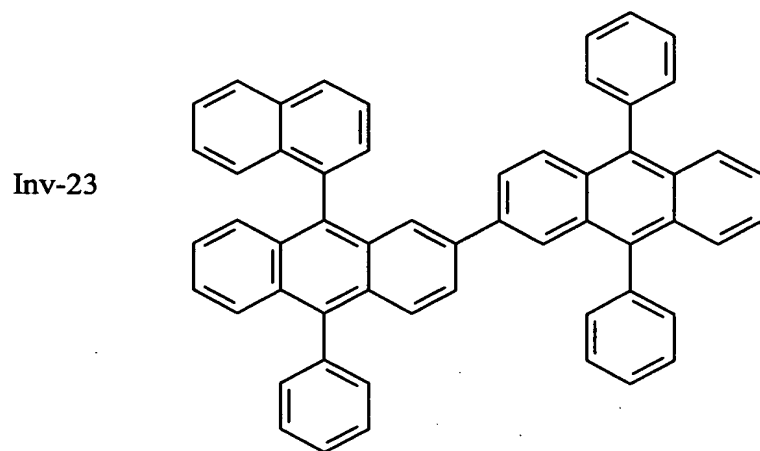
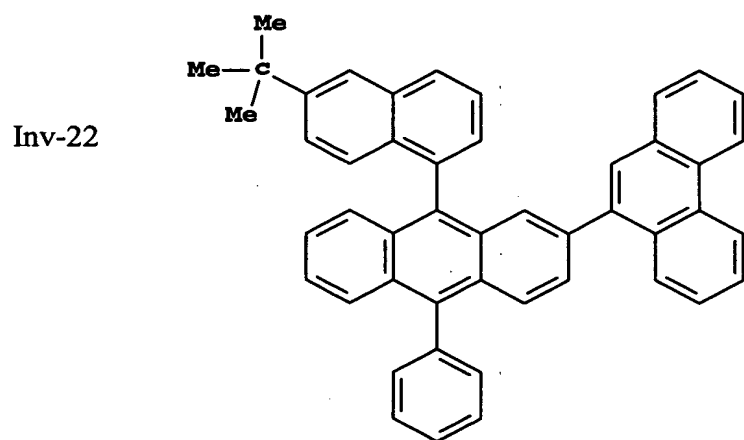


Inv-20



Inv-21





Unless otherwise specifically stated, use of the term "substituted" or "substituent" means any group or atom other than hydrogen. Additionally, when the term "group" is used, it means that when a substituent group contains a substitutable hydrogen, it is also intended to encompass not only the substituent's unsubstituted form, but also its form further substituted with any substituent group or groups as herein mentioned, so long as the substituent does not destroy properties necessary for device utility. Suitably, a substituent group may be halogen or may be bonded to the remainder of the molecule by an atom of carbon, silicon, oxygen, nitrogen, phosphorous, sulfur, selenium, or boron. The substituent may be, for example, halogen, such as chloro, bromo or fluoro; nitro; hydroxyl; cyano; carboxyl; or groups which may be further substituted, such as alkyl, including straight or branched chain or cyclic alkyl, such as methyl, trifluoromethyl, ethyl, *t*-butyl, 3-(2,4-di-*t*-pentylphenoxy) propyl, and tetradecyl; alkenyl, such as ethylene, 2-butene; alkoxy, such as methoxy, ethoxy, propoxy, butoxy, 2-methoxyethoxy, *sec*-butoxy, hexyloxy, 2-ethylhexyloxy, tetradecyloxy, 2-(2,4-di-*t*-pentylphenoxy)ethoxy, and 2-dodecyloxyethoxy; aryl such as phenyl, 4-*t*-butylphenyl, 2,4,6-trimethylphenyl, naphthyl; aryloxy, such as phenoxy, 2-methylphenoxy, alpha- or beta-naphthyloxy, and 4-tolyloxy; carbonamido, such as acetamido, benzamido, butyramido, tetradecanamido, *alpha*-(2,4-di-*t*-pentylphenoxy)acetamido, *alpha*-(2,4-di-*t*-pentylphenoxy)butyramido, *alpha*-(3-pentadecylphenoxy)-hexanamido, *alpha*-(4-hydroxy-3-*t*-butylphenoxy)-tetradecanamido, 2-oxo-pyrrolidin-1-yl, 2-oxo-5-tetradecylpyrrolin-1-yl, *N*-methyltetradecanamido, *N*-succinimido, *N*-phthalimido, 2,5-dioxo-1-oxazolidinyl, 3-dodecyl-2,5-dioxo-1-imidazolyl, and *N*-acetyl-*N*-dodecylamino, ethoxycarbonylamino, phenoxycarbonylamino, benzyloxycarbonylamino, hexadecyloxycarbonylamino, 2,4-di-*t*-butylphenoxycarbonylamino, phenylcarbonylamino, 2,5-(di-*t*-pentylphenyl)carbonylamino, *p*-dodecylphenylcarbonylamino, *p*-tolylcarbonylamino, *N*-methylureido, *N,N*-dimethylureido, *N*-methyl-*N*-dodecylureido, *N*-hexadecylureido, *N,N*-dioctadecylureido, *N,N*-dioctyl-*N'*-ethylureido, *N*-phenylureido, *N,N*-diphenylureido, *N*-phenyl-*N-p*-tolylureido, *N*-(*m*-hexadecylphenyl)ureido, *N,N*-

(2,5-di-*t*-pentylphenyl)-*N'*-ethylureido, and *t*-butylcarbonamido; sulfonamido, such as methylsulfonamido, benzenesulfonamido, *p*-tolylsulfonamido, *p*-dodecylbenzenesulfonamido, *N*-methyltetradecylsulfonamido, *N,N*-dipropylsulfamoylamino, and hexadecylsulfonamido; sulfamoyl, such as *N*-methylsulfamoyl, *N*-ethylsulfamoyl, *N,N*-dipropylsulfamoyl, *N*-hexadecylsulfamoyl, *N,N*-dimethylsulfamoyl, *N*-[3-(dodecyloxy)propyl]sulfamoyl, *N*-[4-(2,4-di-*t*-pentylphenoxy)butyl]sulfamoyl, *N*-methyl-*N*-tetradecylsulfamoyl, and *N*-dodecylsulfamoyl; carbamoyl, such as *N*-methylcarbamoyl, *N,N*-dibutylcarbamoyl, *N*-octadecylcarbamoyl, *N*-[4-(2,4-di-*t*-pentylphenoxy)butyl]carbamoyl, *N*-methyl-*N*-tetradecylcarbamoyl, and *N,N*-dioctylcarbamoyl; acyl, such as acetyl, (2,4-di-*t*-amylphenoxy)acetyl, phenoxycarbonyl, *p*-dodecyloxyphenoxycarbonyl methoxycarbonyl, butoxycarbonyl, tetradecyloxycarbonyl, ethoxycarbonyl, benzyloxycarbonyl, 3-pentadecyloxycarbonyl, and dodecyloxycarbonyl; sulfonyl, such as methoxysulfonyl, octyloxysulfonyl, tetradecyloxysulfonyl, 2-ethylhexyloxysulfonyl, phenoxysulfonyl, 2,4-di-*t*-pentylphenoxysulfonyl, methylsulfonyl, octylsulfonyl, 2-ethylhexylsulfonyl, dodecylsulfonyl, hexadecylsulfonyl, phenylsulfonyl, 4-nonylphenylsulfonyl, and *p*-tolylsulfonyl; sulfonyloxy, such as dodecylsulfonyloxy, and hexadecylsulfonyloxy; sulfinyl, such as methylsulfinyl, octylsulfinyl, 2-ethylhexylsulfinyl, dodecylsulfinyl, hexadecylsulfinyl, phenylsulfinyl, 4-nonylphenylsulfinyl, and *p*-tolylsulfinyl; thio, such as ethylthio, octylthio, benzylthio, tetradecylthio, 2-(2,4-di-*t*-pentylphenoxy)ethylthio, phenylthio, 2-butoxy-5-*t*-octylphenylthio, and *p*-tolylthio; acyloxy, such as acetyloxy, benzoyloxy, octadecanoyloxy, *p*-dodecylamidobenzoyloxy, *N*-phenylcarbamoyloxy, *N*-ethylcarbamoyloxy, and cyclohexylcarbonyloxy; amine, such as phenylanilino, 2-chloroanilino, diethylamine, dodecylamine; imino, such as 1 (*N*-phenylimido)ethyl, *N*-succinimido or 3-benzylhydantoinyl; phosphate, such as dimethylphosphate and ethylbutylphosphate; phosphite, such as diethyl and dihexylphosphite; a heterocyclic group, a heterocyclic oxy group or a heterocyclic thio group, each of which may be substituted and which contain a 3 to 7 membered heterocyclic ring

composed of carbon atoms and at least one hetero atom selected from the group consisting of oxygen, nitrogen, sulfur, phosphorous, or boron. such as 2-furyl, 2-thienyl, 2-benzimidazolyloxy or 2-benzothiazolyl; quaternary ammonium, such as triethylammonium; quaternary phosphonium, such as triphenylphosphonium; and
5 silyloxy, such as trimethylsilyloxy.

If desired, the substituents may themselves be further substituted one or more times with the described substituent groups. The particular substituents used may be selected by those skilled in the art to attain the desired desirable properties for a specific application and can include, for example,
10 electron-withdrawing groups, electron-donating groups, and steric groups. When a molecule may have two or more substituents, the substituents may be joined together to form a ring such as a fused ring unless otherwise provided. Generally, the above groups and substituents thereof may include those having up to 48 carbon atoms, typically 1 to 36 carbon atoms and usually less than 24 carbon
15 atoms, but greater numbers are possible depending on the particular substituents selected.

General Device Architecture

The present invention can be employed in many EL device configurations using small molecule materials, oligomeric materials, polymeric
20 materials, or combinations thereof. These include very simple structures comprising a single anode and cathode to more complex devices, such as passive matrix displays comprised of orthogonal arrays of anodes and cathodes to form pixels, and active-matrix displays where each pixel is controlled independently, for example, with thin film transistors (TFTs).

25 There are numerous configurations of the organic layers wherein the present invention can be successfully practiced. The essential requirements of an OLED are an anode, a cathode, and an organic light-emitting layer located between the anode and cathode. Additional layers may be employed as more fully described hereafter.

30 A typical structure according to the present invention and especially useful for a small molecule device, is shown in FIG. 1 and is comprised

of a substrate **101**, an anode **103**, a hole-injecting layer **105**, a hole-transporting layer **107**, a light-emitting layer **109**, an electron-transporting layer **111**, and a cathode **113**. These layers are described in detail below. Note that the substrate **101** may alternatively be located adjacent to the cathode **113**, or the substrate **101** may actually constitute the anode **103** or cathode **113**. The organic layers between the anode **103** and cathode **113** are conveniently referred to as the organic EL element. Also, the total combined thickness of the organic layers is desirably less than 500 nm. If the device includes phosphorescent material, a hole-blocking layer, located between the light-emitting layer and the electron-transporting layer, may be present.

The anode **103** and cathode **113** of the OLED are connected to a voltage/current source through electrical conductors. The OLED is operated by applying a potential between the anode **103** and cathode **113** such that the anode **103** is at a more positive potential than the cathode **113**. Holes are injected into the organic EL element from the anode **103** and electrons are injected into the organic EL element at the cathode **113**. Enhanced device stability can sometimes be achieved when the OLED is operated in an AC mode where, for some time period in the AC cycle, the potential bias is reversed and no current flows. An example of an AC driven OLED is described in US 5,552,678.

Substrate

The OLED device of this invention is typically provided over a supporting substrate **101** where either the cathode **113** or anode **103** can be in contact with the substrate. The electrode in contact with the substrate **101** is conveniently referred to as the bottom electrode. Conventionally, the bottom electrode is the anode **103**, but this invention is not limited to that configuration. The substrate **101** can either be light transmissive or opaque, depending on the intended direction of light emission. The light transmissive property is desirable for viewing the EL emission through the substrate **101**. Transparent glass or plastic is commonly employed in such cases. The substrate **101** can be a complex structure comprising multiple layers of materials. This is typically the case for active matrix substrates wherein TFTs are provided below the OLED layers. It is

still necessary that the substrate **101**, at least in the emissive pixelated areas, be comprised of largely transparent materials such as glass or polymers. For applications where the EL emission is viewed through the top electrode, the transmissive characteristic of the bottom support is immaterial, and therefore the substrate can be light transmissive, light absorbing or light reflective. Substrates for use in this case include, but are not limited to, glass, plastic, semiconductor materials such as silicon, ceramics, and circuit board materials. Again, the substrate **101** can be a complex structure comprising multiple layers of materials such as found in active matrix TFT designs. It is necessary to provide in these device configurations a light-transparent top electrode.

Anode

When the desired electroluminescent light emission (EL) is viewed through the anode, the anode **103** should be transparent or substantially transparent to the emission of interest. Common transparent anode materials used in this invention are indium-tin oxide (ITO), indium-zinc oxide (IZO) and tin oxide, but other metal oxides can work including, but not limited to, aluminum- or indium-doped zinc oxide, magnesium-indium oxide, and nickel-tungsten oxide. In addition to these oxides, metal nitrides, such as gallium nitride, and metal selenides, such as zinc selenide, and metal sulfides, such as zinc sulfide, can be used as the anode **103**. For applications where EL emission is viewed only through the cathode **113**, the transmissive characteristics of the anode **103** are immaterial and any conductive material can be used, transparent, opaque or reflective. Example conductors for this application include, but are not limited to, gold, iridium, molybdenum, palladium, and platinum. Typical anode materials, transmissive or otherwise, have a work function of 4.1 eV or greater. Desired anode materials are commonly deposited by any suitable means such as evaporation, sputtering, chemical vapor deposition, or electrochemical means. Anodes can be patterned using well-known photolithographic processes. Optionally, anodes may be polished prior to application of other layers to reduce surface roughness so as to minimize short circuits or enhance reflectivity.

Cathode

When light emission is viewed solely through the anode 103, the cathode 113 used in this invention can be comprised of nearly any conductive material. Desirable materials have good film-forming properties to ensure good contact with the underlying organic layer, promote electron injection at low voltage, and have good stability. Useful cathode materials often contain a low work function metal (< 4.0 eV) or metal alloy. One useful cathode material is comprised of a Mg:Ag alloy wherein the percentage of silver is in the range of 1 to 20 %, as described in U.S. Patent No. 4,885,221. Another suitable class of cathode materials includes bilayers comprising the cathode and a thin electron-injection layer (EIL) in contact with an organic layer (e.g., an electron transporting layer (ETL)), the cathode being capped with a thicker layer of a conductive metal. Here, the EIL preferably includes a low work function metal or metal salt, and if so, the thicker capping layer does not need to have a low work function. One such cathode is comprised of a thin layer of LiF followed by a thicker layer of Al as described in U.S. Patent No. 5,677,572. An ETL material doped with an alkali metal, for example, Li-doped Alq, is another example of a useful EIL. Other useful cathode material sets include, but are not limited to, those disclosed in U.S. Patent Nos. 5,059,861, 5,059,862, and 6,140,763.

When light emission is viewed through the cathode, the cathode 113 must be transparent or nearly transparent. For such applications, metals must be thin or one must use transparent conductive oxides, or a combination of these materials. Optically transparent cathodes have been described in more detail in US 4,885,211, US 5,247,190, JP 3,234,963, US 5,703,436, US 5,608,287, US 5,837,391, US 5,677,572, US 5,776,622, US 5,776,623, US 5,714,838, US 5,969,474, US 5,739,545, US 5,981,306, US 6,137,223, US 6,140,763, US 6,172,459, EP 1 076 368, US 6,278,236, and US 6,284,3936. Cathode materials are typically deposited by any suitable method such as evaporation, sputtering, or chemical vapor deposition. When needed, patterning can be achieved through many well known methods including, but not limited to, through-mask deposition,

integral shadow masking as described in US 5,276,380 and EP 0 732 868, laser ablation, and selective chemical vapor deposition.

Hole-Injecting Layer (HIL)

A hole-injecting layer 105 may be provided between anode 103 and hole-transporting layer 107. The hole-injecting layer can serve to improve the film formation property of subsequent organic layers and to facilitate injection of holes into the hole-transporting layer 107. Suitable materials for use in the hole-injecting layer 105 include, but are not limited to, porphyrinic compounds as described in US 4,720,432, plasma-deposited fluorocarbon polymers as described in US 6,208,075, and some aromatic amines, for example, MTDATA (4,4',4"-tris[(3-methylphenyl)phenylamino]triphenylamine). Alternative hole-injecting materials reportedly useful in organic EL devices are described in EP 0 891 121 A1 and EP 1 029 909 A1. A hole-injection layer is conveniently used in the present invention, and is desirably a plasma-deposited fluorocarbon polymer. The thickness of a hole-injection layer containing a plasma-deposited fluorocarbon polymer can be in the range of 0.2 nm to 15 nm and suitably in the range of 0.3 to 1.5 nm.

Hole-Transporting Layer (HTL)

While not always necessary, it is often useful to include a hole-transporting layer in an OLED device. The hole-transporting layer 107 of the organic EL device contains at least one hole-transporting compound such as an aromatic tertiary amine, where the latter is understood to be a compound containing at least one trivalent nitrogen atom that is bonded only to carbon atoms, at least one of which is a member of an aromatic ring. In one form the aromatic tertiary amine can be an arylamine, such as a monoarylamine, diarylamine, triarylamine, or a polymeric arylamine. Exemplary monomeric triarylaminines are illustrated by Klupfel et al. US 3,180,730. Other suitable triarylaminines substituted with one or more vinyl radicals and/or comprising at least one active hydrogen containing group are disclosed by Brantley et al US 3,567,450 and US 3,658,520.

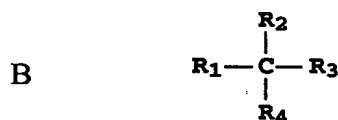
A more preferred class of aromatic tertiary amines is those which include at least two aromatic tertiary amine moieties as described in US 4,720,432

and US 5,061,569. Such compounds include those represented by structural formula (A).



wherein Q₁ and Q₂ are independently selected aromatic tertiary amine moieties
5 and G is a linking group such as an arylene, cycloalkylene, or alkylene group of a carbon to carbon bond. In one embodiment, at least one of Q₁ or Q₂ contains a polycyclic fused ring structure, e.g., a naphthalene. When G is an aryl group, it is conveniently a phenylene, biphenylene, or naphthalene moiety.

A useful class of triaryl amines satisfying structural formula (A) and
10 containing two triarylamine moieties is represented by structural formula (B):



where

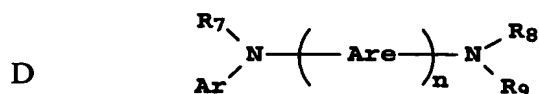
R₁ and R₂ each independently represents a hydrogen atom, an aryl group, or an alkyl group or R₁ and R₂ together represent the atoms completing a cycloalkyl group; and

15 R₃ and R₄ each independently represents an aryl group, which is in turn substituted with a diaryl substituted amino group, as indicated by structural formula (C):



wherein R₅ and R₆ are independently selected aryl groups. In one embodiment, at least one of R₅ or R₆ contains a polycyclic fused ring structure, e.g., a naphthalene.

20 Another class of aromatic tertiary amines is the tetraaryldiamines. Desirable tetraaryldiamines include two diarylamino groups, such as indicated by formula (C), linked through an arylene group. Useful tetraaryldiamines include those represented by formula (D).



wherein

each Are is an independently selected arylene group, such as a phenylene or anthracene moiety,

n is an integer of from 1 to 4, and

5 Ar, R₇, R₈, and R₉ are independently selected aryl groups.

In a typical embodiment, at least one of Ar, R₇, R₈, and R₉ is a polycyclic fused ring structure, e.g., a naphthalene.

The various alkyl, alkylene, aryl, and arylene moieties of the foregoing structural formulae (A), (B), (C), (D), can each in turn be substituted.

10 Typical substituents include alkyl groups, alkoxy groups, aryl groups, aryloxy groups, and halide such as fluoride, chloride, and bromide. The various alkyl and alkylene moieties typically contain from about 1 to 6 carbon atoms. The cycloalkyl moieties can contain from 3 to about 10 carbon atoms, but typically contain five, six, or seven ring carbon atoms--e.g., cyclopentyl, cyclohexyl, and
15 cycloheptyl ring structures. The aryl and arylene moieties are usually phenyl and phenylene moieties.

The hole-transporting layer can be formed of a single tertiary amine compound or a mixture of such compounds. Specifically, one may employ a triarylamine, such as a triarylamine satisfying the formula (B), in combination
20 with a tetraaryldiamine, such as indicated by formula (D). Illustrative of useful aromatic tertiary amines are the following:

1,1-Bis(4-di-*p*-tolylaminophenyl)cyclohexane (TAPC)

1,1-Bis(4-di-*p*-tolylaminophenyl)-4-methylcyclohexane

1,1-Bis(4-di-*p*-tolylaminophenyl)-4-phenylcyclohexane

25 1,1-Bis(4-di-*p*-tolylaminophenyl)-3-phenylpropane (TAPPP)

N,N,N',N'-tetraphenyl-4,4'''-diamino-1,1':4',1'':4'',1'''-quaterphenyl

Bis(4-dimethylamino-2-methylphenyl)phenylmethane

1,4-bis[2-[4-[*N,N*-di(*p*-tolyl)amino]phenyl]vinyl]benzene (BDTAPVB)

N,N,N',N'-Tetra-*p*-tolyl-4,4'-diaminobiphenyl (TTB)

- N,N,N',N'*-Tetraphenyl-4,4'-diaminobiphenyl
N,N,N',N'-tetra-1-naphthyl-4,4'-diaminobiphenyl
N,N,N',N'-tetra-2-naphthyl-4,4'-diaminobiphenyl
N-Phenylcarbazole
- 5 4,4'-Bis[*N*-(1-naphthyl)-*N*-phenylamino]biphenyl (NPB)
 4,4'-Bis[*N*-(1-naphthyl)-*N*-(2-naphthyl)amino]biphenyl (TNB)
 4,4'-Bis[*N*-(1-naphthyl)-*N*-phenylamino]*p*-terphenyl
 4,4'-Bis[*N*-(2-naphthyl)-*N*-phenylamino]biphenyl
 4,4'-Bis[*N*-(3-acenaphthenyl)-*N*-phenylamino]biphenyl
- 10 1,5-Bis[*N*-(1-naphthyl)-*N*-phenylamino]naphthalene
 4,4'-Bis[*N*-(9-anthryl)-*N*-phenylamino]biphenyl
 4,4'-Bis[*N*-(1-anthryl)-*N*-phenylamino]-*p*-terphenyl
 4,4'-Bis[*N*-(2-phenanthryl)-*N*-phenylamino]biphenyl
 4,4'-Bis[*N*-(8-fluoranthryl)-*N*-phenylamino]biphenyl
- 15 4,4'-Bis[*N*-(2-pyrenyl)-*N*-phenylamino]biphenyl
 4,4'-Bis[*N*-(2-naphthacenyl)-*N*-phenylamino]biphenyl
 4,4'-Bis[*N*-(2-perylenyl)-*N*-phenylamino]biphenyl
 4,4'-Bis[*N*-(1-coronenyl)-*N*-phenylamino]biphenyl
- 20 2,6-Bis(di-*p*-tolylamino)naphthalene
 2,6-Bis[di-(1-naphthyl)amino]naphthalene
 2,6-Bis[*N*-(1-naphthyl)-*N*-(2-naphthyl)amino]naphthalene
 N,N,N',N'-Tetra(2-naphthyl)-4,4''-diamino-*p*-terphenyl
 4,4'-Bis{*N*-phenyl-*N*-[4-(1-naphthyl)-phenyl]amino}biphenyl
 2,6-Bis[*N,N*-di(2-naphthyl)amino]fluorene
- 25 4,4',4''-tris[(3-methylphenyl)phenylamino]triphenylamine (MTDATA)
 4,4'-Bis[*N*-(3-methylphenyl)-*N*-phenylamino]biphenyl (TPD)

Another class of useful hole-transporting materials includes polycyclic aromatic compounds as described in EP 1 009 041. Tertiary aromatic amines with more than two amine groups may be used including oligomeric materials. In addition, polymeric hole-transporting materials can be used such as poly(*N*-vinylcarbazole) (PVK), polythiophenes, polypyrrole, polyaniline, and

copolymers such as poly(3,4-ethylenedioxythiophene) / poly(4-styrenesulfonate) also called PEDOT/PSS. It is also possible for the hole-transporting layer to comprise two or more sublayers of differing compositions, the composition of each sublayer being as described above. The thickness of the hole-transporting layer can be between 10 and about 500 nm and suitably between 50 and 300 nm.

Light-Emitting Layer (LEL)

Light emitting materials useful in the EL device include fluorescent materials. As more fully described in U.S. Patent Nos. 4,769,292 and 5,935,721, the light-emitting layer (LEL) of the organic EL element includes a luminescent material where electroluminescence is produced as a result of electron-hole pair recombination. The light-emitting layer can be comprised of a single material, but more commonly consists of a host material doped with a guest emitting material or materials where light emission comes primarily from the emitting materials and can be of any color.

The host materials of the invention may be used in combination with additional host materials, which may be in the same layer or a different layer. The host materials in the light-emitting layer can be an electron-transporting material, as defined below, a hole-transporting material, as defined above, or another material or combination of materials that support hole-electron recombination. Fluorescent emitting materials are typically incorporated at 0.01 to 10 % by weight of the host material.

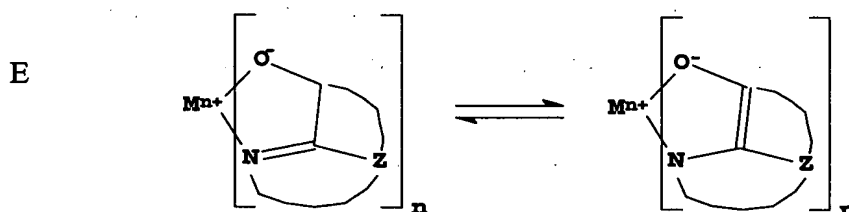
The host and emitting materials can be small non-polymeric molecules or polymeric materials such as polyfluorenes and polyvinylarylenes (e.g., poly(*p*-phenylenevinylene), PPV). In the case of polymers, small-molecule emitting materials can be molecularly dispersed into a polymeric host, or the emitting materials can be added by copolymerizing a minor constituent into a host polymer. Host materials may be mixed together in order to improve film formation, electrical properties, light emission efficiency, operating lifetime, or manufacturability. The host may comprise a material that has good hole-transporting properties and a material that has good electron-transporting properties.

An important relationship for choosing a fluorescent material as a guest emitting material is a comparison of the excited singlet-state energies of the host and the fluorescent material. It is highly desirable that the excited singlet-state energy of the fluorescent material be lower than that of the host material.

- 5 The excited singlet-state energy is defined as the difference in energy between the emitting singlet state and the ground state. For non-emissive hosts, the lowest excited state of the same electronic spin as the ground state is considered the emitting state.

Host and emitting materials known to be of use include, but are not
 10 limited to, those disclosed in US 4,768,292, US 5,141,671, US 5,150,006, US 5,151,629, US 5,405,709, US 5,484,922, US 5,593,788, US 5,645,948, US 5,683,823, US 5,755,999, US 5,928,802, US 5,935,720, US 5,935,721, and US 6,020,078.

Metal complexes of 8-hydroxyquinoline and similar derivatives,
 15 also known as metal-chelated oxinoid compounds (Formula E), constitute one class of useful host compounds capable of supporting electroluminescence, and are particularly suitable for light emission of wavelengths longer than 500 nm, e.g., green, yellow, orange, and red.



wherein

20 M represents a metal;

n is an integer of from 1 to 4; and

Z independently in each occurrence represents the atoms completing a nucleus having at least two fused aromatic rings.

From the foregoing it is apparent that the metal can be monovalent,
 25 divalent, trivalent, or tetravalent metal. The metal can, for example, be an alkali metal, such as lithium, sodium, or potassium; an alkaline earth metal, such as

magnesium or calcium; a trivalent metal, such aluminum or gallium, or another metal such as zinc or zirconium. Generally any monovalent, divalent, trivalent, or tetravalent metal known to be a useful chelating metal can be employed.

5 Z completes a heterocyclic nucleus containing at least two fused aromatic rings, at least one of which is an azole or azine ring. Additional rings, including both aliphatic and aromatic rings, can be fused with the two required rings, if required. To avoid adding molecular bulk without improving on function the number of ring atoms is usually maintained at 18 or less.

10 Illustrative of useful chelated oxinoid compounds are the following:

CO-1: Aluminum trisoxine [alias, tris(8-quinolinolato)aluminum(III)]

CO-2: Magnesium bisoxine [alias, bis(8-quinolinolato)magnesium(II)]

CO-3: Bis[benzo{f}-8-quinolinolato]zinc (II)

15 CO-4: Bis(2-methyl-8-quinolinolato)aluminum(III)- μ -oxo-bis(2-methyl-8-quinolinolato) aluminum(III)

CO-5: Indium trisoxine [alias, tris(8-quinolinolato)indium]

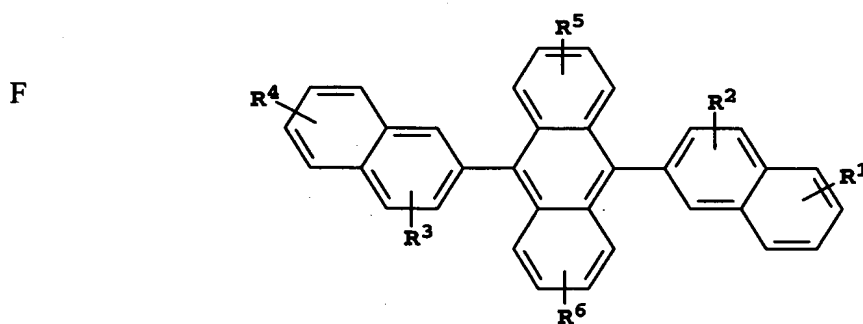
CO-6: Aluminum tris(5-methyloxine) [alias, tris(5-methyl-8-quinolinolato) aluminum(III)]

CO-7: Lithium oxine [alias, (8-quinolinolato)lithium(I)]

20 CO-8: Gallium oxine [alias, tris(8-quinolinolato)gallium(III)]

CO-9: Zirconium oxine [alias, tetra(8-quinolinolato)zirconium(IV)]

Derivatives of 9,10-di-(2-naphthyl)anthracene (Formula F) constitute one class of useful host materials capable of supporting electroluminescence, and are particularly suitable for light emission of
25 wavelengths longer than 400 nm, e.g., blue, green, yellow, orange or red.

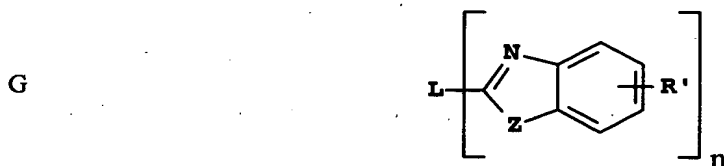


wherein: R^1 , R^2 , R^3 , R^4 , R^5 , and R^6 represent one or more substituents on each ring where each substituent is individually selected from the following groups:

- Group 1: hydrogen, or alkyl of from 1 to 24 carbon atoms;
- 5 Group 2: aryl or substituted aryl of from 5 to 20 carbon atoms;
- Group 3: carbon atoms from 4 to 24 necessary to complete a fused aromatic ring of anthracenyl; pyrenyl, or perylenyl;
- Group 4: heteroaryl or substituted heteroaryl of from 5 to 24 carbon atoms as necessary to complete a fused heteroaromatic ring of furyl, thienyl, pyridyl,
- 10 quinolinyl or other heterocyclic systems;
- Group 5: alkoxyamino, alkylamino, or arylamino of from 1 to 24 carbon atoms; and
- Group 6: fluorine, chlorine, bromine or cyano.

15 Illustrative examples include 9,10-di-(2-naphthyl)anthracene and *t*-butyl-9,10-di-(2-naphthyl)anthracene. Other anthracene derivatives can be useful as a host in the LEL, including derivatives of 9,10-bis[4-(2,2-diphenylethenyl)phenyl]anthracene.

20 Benzazole derivatives (Formula G) constitute another class of useful host materials capable of supporting electroluminescence, and are particularly suitable for light emission of wavelengths longer than 400 nm, e.g., blue, green, yellow, orange or red.



wherein:

n is an integer of 3 to 8;

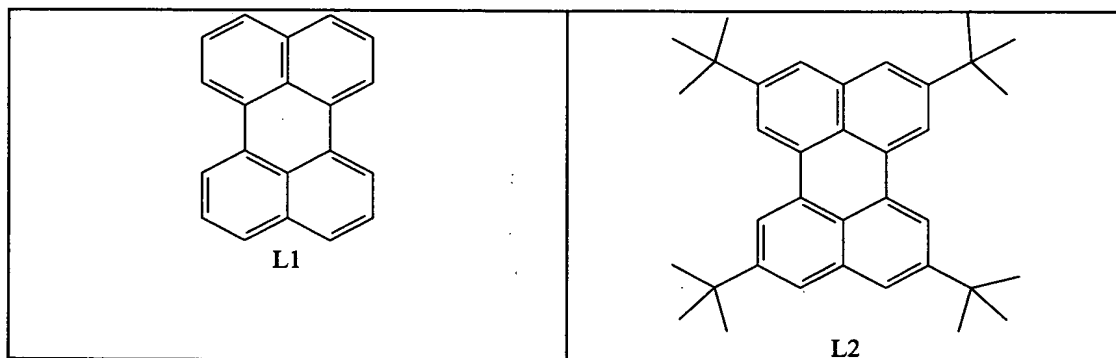
Z is O, NR or S; and

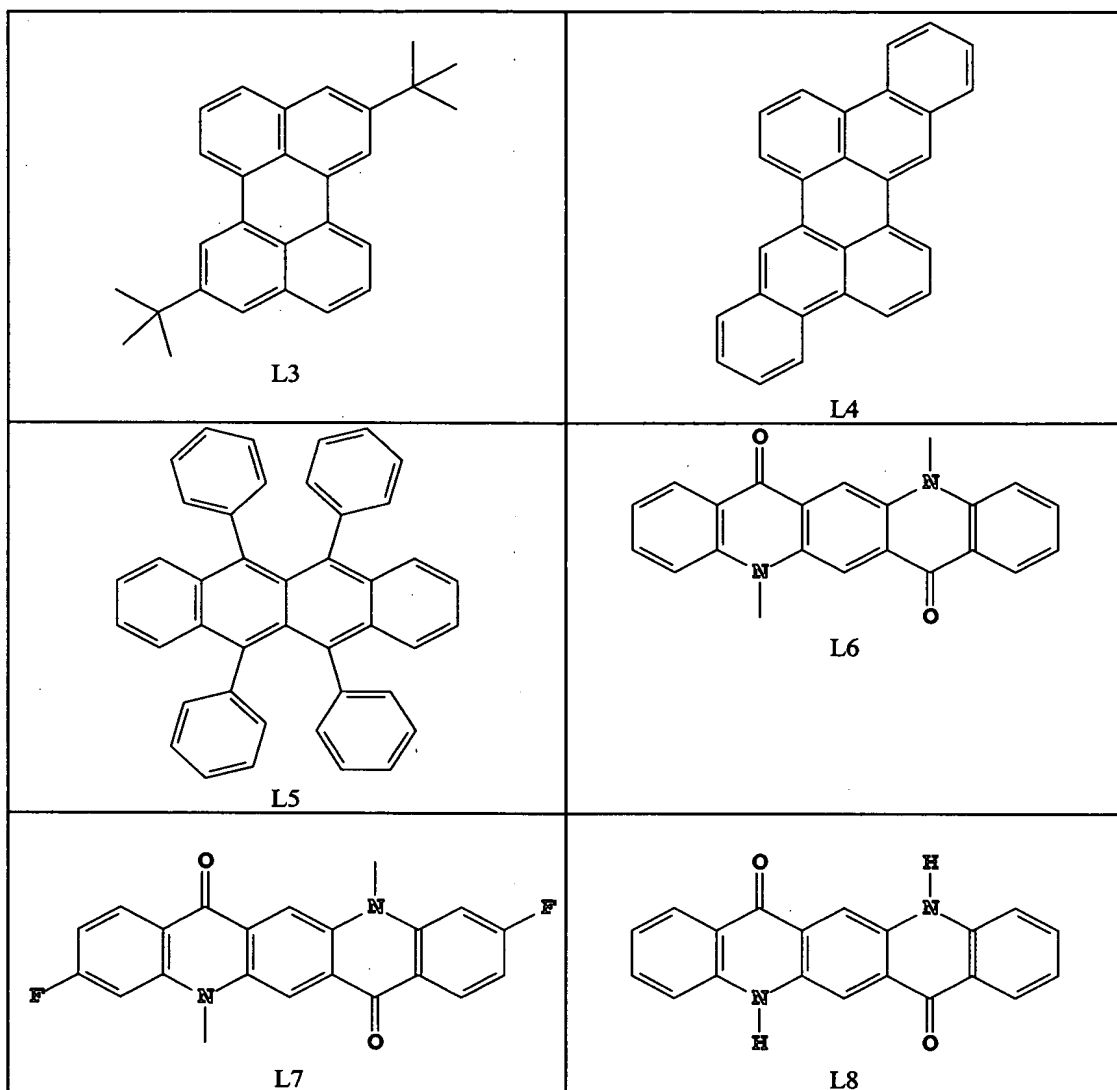
R and R' are individually hydrogen; alkyl of from 1 to 24 carbon atoms,
5 for example, propyl, t-butyl, heptyl, and the like; aryl or hetero-atom substituted
aryl of from 5 to 20 carbon atoms for example phenyl and naphthyl, furyl, thienyl,
pyridyl, quinoliny and other heterocyclic systems; or halo such as chloro, fluoro;
or atoms necessary to complete a fused aromatic ring; and

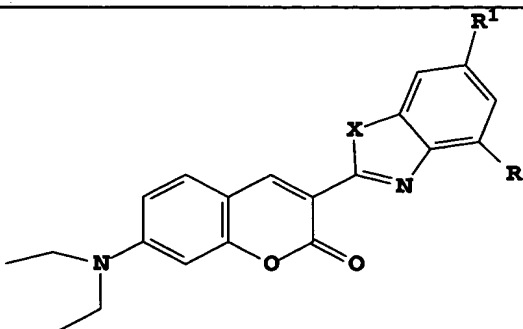
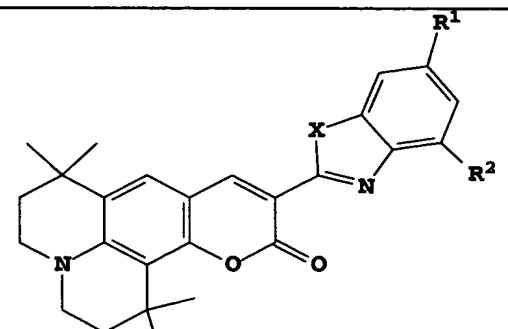
L is a linkage unit consisting of alkyl, aryl, substituted alkyl, or substituted
10 aryl, which connects the multiple benzazoles together. L may be either conjugated
with the multiple benzazoles or not in conjugation with them. An example of a
useful benzazole is 2,2',2''-(1,3,5-phenylene)tris[1-phenyl-1H-benzimidazole].

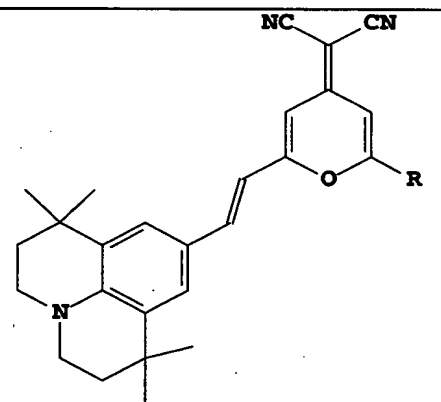
Styrylarylene derivatives as described in U.S. Patent 5,121,029 and JP
08333569 are also useful hosts for blue emission. For example, 9,10-bis[4-(2,2-
15 diphenylethenyl)phenyl]anthracene and 4,4'-bis(2,2-diphenylethenyl)-1,1'-biphenyl
(DPVBi) are useful hosts for blue emission.

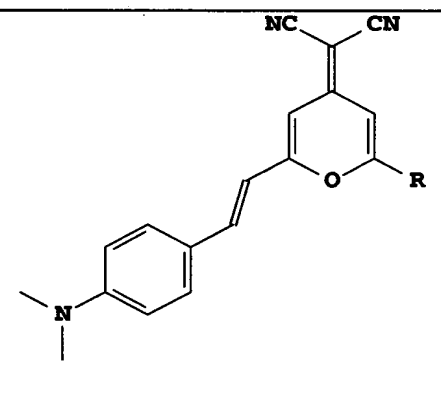
Useful fluorescent emitting materials include, but are not limited
to, derivatives of anthracene, tetracene, xanthene, perylene, rubrene, coumarin,
rhodamine, and quinacridone, dicyanomethylenepyran compounds, thiopyran
20 compounds, polymethine compounds, pyrylium and thiapyrylium compounds,
fluorene derivatives, perflanthene derivatives, indenoperylene derivatives,
bis(aziny)amine boron compounds, bis(aziny)methane compounds, and
carbostyryl compounds. Illustrative examples of useful materials include, but are
not limited to, the following:

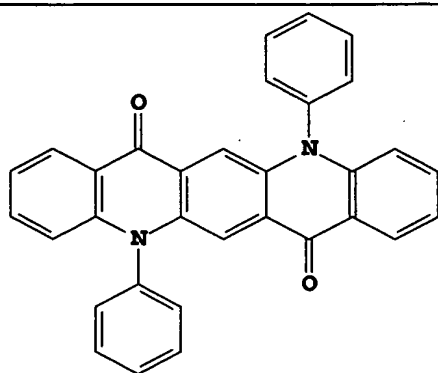




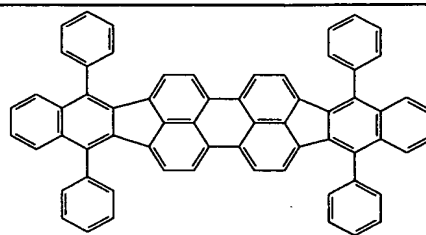
							
	<u>X</u>	<u>R1</u>	<u>R2</u>		<u>X</u>	<u>R1</u>	<u>R2</u>
L9	O	H	H	L23	O	H	H
L10	O	H	Methyl	L24	O	H	Methyl
L11	O	Methyl	H	L25	O	Methyl	H
L12	O	Methyl	Methyl	L26	O	Methyl	Methyl
L13	O	H	<i>t</i> -butyl	L27	O	H	<i>t</i> -butyl
L14	O	<i>t</i> -butyl	H	L28	O	<i>t</i> -butyl	H
L15	O	<i>t</i> -butyl	<i>t</i> -butyl	L29	O	<i>t</i> -butyl	<i>t</i> -butyl
L16	S	H	H	L30	S	H	H
L17	S	H	Methyl	L31	S	H	Methyl
L18	S	Methyl	H	L32	S	Methyl	H
L19	S	Methyl	Methyl	L33	S	Methyl	Methyl
L20	S	H	<i>t</i> -butyl	L34	S	H	<i>t</i> -butyl
L21	S	<i>t</i> -butyl	H	L35	S	<i>t</i> -butyl	H
L22	S	<i>t</i> -butyl	<i>t</i> -butyl	L36	S	<i>t</i> -butyl	<i>t</i> -butyl

		
	<u>R</u>	
L37	phenyl	
L38	methyl	
L39	<i>t</i> -butyl	
L40	mesityl	

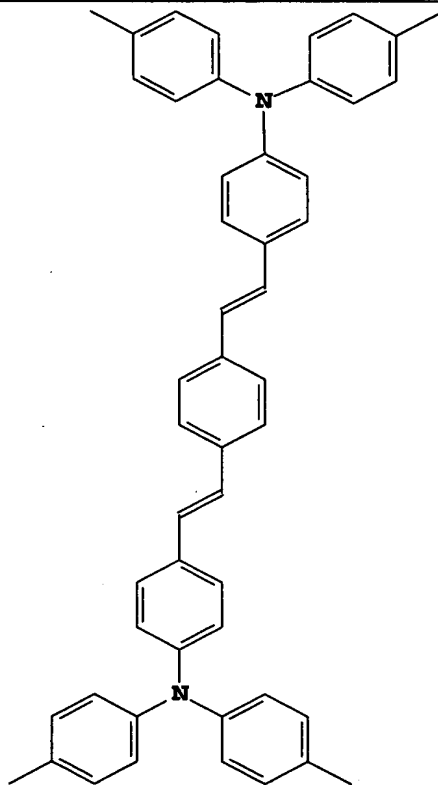
		
	<u>R</u>	
L41	phenyl	
L42	methyl	
L43	<i>t</i> -butyl	
L44	mesityl	



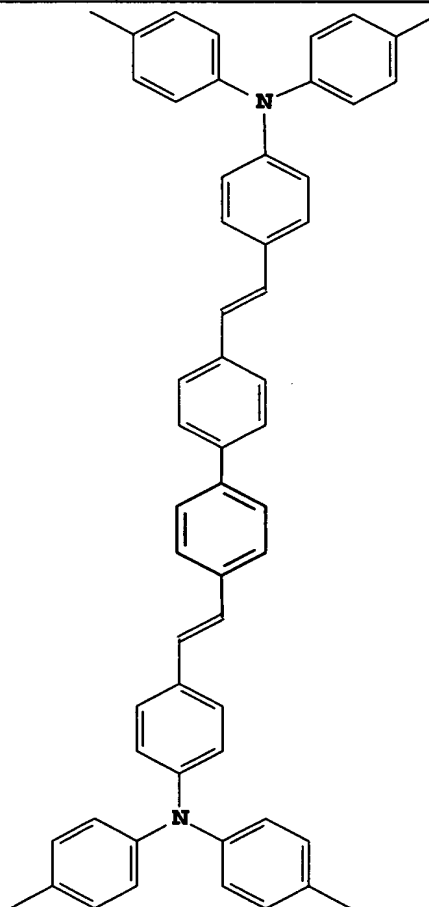
L45



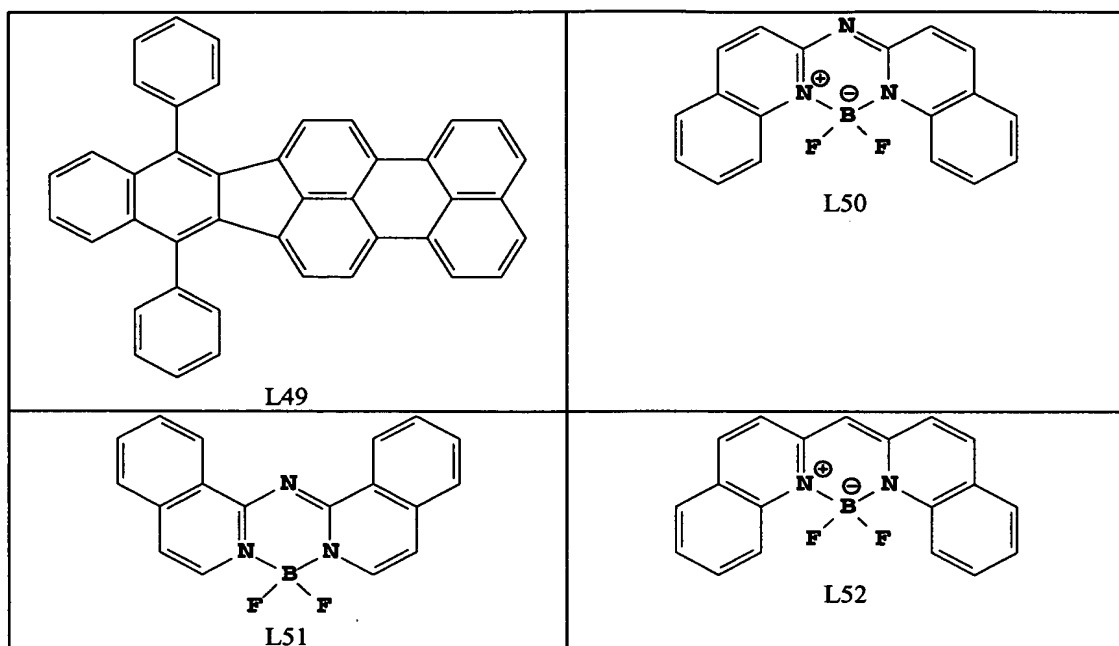
L46



L47



L48



In addition to fluorescent light-emitting materials, light-emitting phosphorescent materials may be used in the EL device. For convenience, the phosphorescent complex guest material may be referred to herein as a phosphorescent material. The phosphorescent material typically includes one or more ligands, for example monoanionic ligands that can be coordinated to a metal through an sp^2 carbon and a heteroatom. Conveniently, the ligand can be phenylpyridine (ppy) or derivatives or analogs thereof. Examples of some useful phosphorescent organometallic materials include tris(2-phenylpyridinato- $N, C^{2'}$)iridium(III), bis(2-phenylpyridinato- $N, C^{2'}$)iridium(III)(acetylacetonate), and bis(2-phenylpyridinato- $N, C^{2'}$)platinum(II). Usefully, many phosphorescent organometallic materials emit in the green region of the spectrum, that is, with a maximum emission in the range of 510 to 570 nm.

Phosphorescent materials may be used singly or in combinations other phosphorescent materials, either in the same or different layers. Phosphorescent materials and suitable hosts are described in WO 00/57676, WO 00/70655, WO 01/41512 A1, WO 02/15645 A1, US 2003/0017361 A1, WO 01/93642 A1, WO 01/39234 A2, US 6,458,475 B1, WO 02/071813 A1, US 6,573,651 B2, US 2002/0197511 A1, WO 02/074015 A2, US 6,451,455 B1, US

2003/ 0072964 A1, US 2003 / 0068528 A1, US 6,413,656 B1, US 6,515,298 B2,
US 6,451,415 B1, US 6,097,147, US 2003/0124381 A1, US 2003/0059646 A1,
US 2003/0054198 A1, EP 1 239 526 A2, EP 1 238 981 A2, EP 1 244 155 A2, US
2002/0100906 A1, US 2003 / 0068526 A1, US 2003/0068535 A1, JP
5 2003073387A, JP 2003 073388A, US 2003/0141809 A1, US 2003/0040627 A1,
JP 2003059667A, JP 2003073665A, and US 2002/0121638 A1.

The emission wavelengths of cyclometallated Ir(III) complexes of
the type IrL_3 and $\text{IrL}_2\text{L}'$, such as the green-emitting *fac*-tris(2-phenylpyridinato-
 $N, C^{2'}$)iridium(III) and bis(2-phenylpyridinato- $N, C^{2'}$)iridium(III)(acetylacetonate)
10 may be shifted by substitution of electron donating or withdrawing groups at
appropriate positions on the cyclometallating ligand L, or by choice of different
heterocycles for the cyclometallating ligand L. The emission wavelengths may
also be shifted by choice of the ancillary ligand L'. Examples of red emitters are
the bis(2-(2'-benzothienyl)pyridinato- $N, C^{3'}$)iridium(III)(acetylacetonate) and
15 tris(2-phenylisoquinolinato- N, C)iridium(III). A blue-emitting example is bis(2-
(4,6-difluorophenyl)-pyridinato- $N, C^{2'}$)iridium(III)(picolinate).

Red electrophosphorescence has been reported, using bis(2-(2'-
benzo[4,5-a]thienyl)pyridinato- N, C^3) iridium (acetylacetonate) [$\text{Btp}_2\text{Ir}(\text{acac})$] as
the phosphorescent material (C. Adachi, S. Lamansky, M. A. Baldo, R. C. Kwong,
20 M. E. Thompson, and S. R. Forrest, *App. Phys. Lett.*, **78**, 1622-1624 (2001)).

Other important phosphorescent materials include cyclometallated
Pt(II) complexes such as cis-bis(2-phenylpyridinato- $N, C^{2'}$)platinum(II), cis-bis(2-
(2'-thienyl)pyridinato- $N, C^{3'}$) platinum(II), cis-bis(2-(2'-thienyl)quinolinato- $N, C^{5'}$)
platinum(II), or (2-(4,6-difluorophenyl)pyridinato- $N, C^{2'}$) platinum (II)
25 (acetylacetonate). Pt (II) porphyrin complexes such as 2,3,7,8,12,13,17,18-
octaethyl-21H, 23H-porphine platinum(II) are also useful phosphorescent
materials.

Still other examples of useful phosphorescent materials include
coordination complexes of the trivalent lanthanides such as Tb^{3+} and Eu^{3+} (J. Kido
30 et al., *Appl. Phys. Lett.*, **65**, 2124 (1994)).

Suitable host materials for phosphorescent materials should be selected so that transfer of a triplet exciton can occur efficiently from the host material to the phosphorescent material but cannot occur efficiently from the phosphorescent material to the host material. Therefore, it is highly desirable that the triplet energy of the phosphorescent material be lower than the triplet energy of the host. Generally speaking, a large triplet energy implies a large optical bandgap. However, the band gap of the host should not be chosen so large as to cause an unacceptable barrier to injection of charge carriers into the light-emitting layer and an unacceptable increase in the drive voltage of the OLED. Suitable host materials are described in WO 00/70655 A2; 01/39234 A2; 01/ 93642 A1; 02/074015 A2; 02/15645 A1, and US 20020117662. Suitable hosts include certain aryl amines, triazoles, indoles and carbazole compounds. Examples of desirable hosts are 4,4'-*N,N'*-dicarbazole-biphenyl, otherwise known as 4,4'-bis(carbazol-9-yl)biphenyl or CBP; 4,4'-*N,N'*-dicarbazole-2,2'-dimethyl-biphenyl, otherwise known as 2,2'-dimethyl-4,4'-bis(carbazol-9-yl)biphenyl or CDBP; 1,3-bis(*N,N'*-dicarbazole)benzene, otherwise known as 1,3-bis(carbazol-9-yl)benzene, and poly(*N*-vinylcarbazole), including their derivatives.

Desirable host materials are capable of forming a continuous film.

Hole-Blocking Layer (HBL)

In addition to suitable hosts, an OLED device employing a phosphorescent material often requires at least one hole-blocking layer placed between the electron-transporting layer 111 and the light-emitting layer 109 to help confine the excitons and recombination events to the light-emitting layer comprising the host and phosphorescent material. In this case, there should be an energy barrier for hole migration from the host into the hole-blocking layer, while electrons should pass readily from the hole-blocking layer into the light-emitting layer comprising a host and a phosphorescent material. The first requirement entails that the ionization potential of the hole-blocking layer be larger than that of the light-emitting layer 109, desirably by 0.2 eV or more. The second requirement entails that the electron affinity of the hole-blocking layer not greatly exceed that of the light-emitting layer 109, and desirably be either less than that of light-

emitting layer or not exceed that of the light-emitting layer by more than about 0.2 eV.

When used with an electron-transporting layer whose characteristic luminescence is green, such as an Alq-containing electron-transporting layer as described below, the requirements concerning the energies of the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) of the material of the hole-blocking layer frequently result in a characteristic luminescence of the hole-blocking layer at shorter wavelengths than that of the electron-transporting layer, such as blue, violet, or ultraviolet luminescence. Thus, it is desirable that the characteristic luminescence of the material of a hole-blocking layer be blue, violet, or ultraviolet. It is further desirable, but not absolutely required, that the triplet energy of the hole-blocking material be greater than that of the phosphorescent material. Suitable hole-blocking materials are described in WO 00/70655A2 and WO 01/93642 A1. Two examples of useful hole-blocking materials are bathocuproine (BCP) and bis(2-methyl-8-quinolinolato)(4-phenylphenolato)aluminum(III) (BALq). The characteristic luminescence of BCP is in the ultraviolet, and that of BALq is blue. Metal complexes other than BALq are also known to block holes and excitons as described in US 20030068528. In addition, US 20030175553 A1 describes the use of *fac*-tris(1-phenylpyrazolato-*N,C*^{2'})iridium(III) (Irppz) for this purpose.

When a hole-blocking layer is used, its thickness can be between 2 and 100 nm and suitably between 5 and 10 nm.

Electron-Transporting Layer (ETL)

Desirable thin film-forming materials for use in forming the electron-transporting layer 111 of the organic EL devices of this invention are metal-chelated oxinoid compounds, including chelates of oxine itself (also commonly referred to as 8-quinolinol or 8-hydroxyquinoline). Such compounds help to inject and transport electrons, exhibit high levels of performance, and are readily fabricated in the form of thin films. Exemplary of contemplated oxinoid compounds are those satisfying structural formula (E), previously described.

Other electron-transporting materials suitable for use in the electron-transporting layer 111 include various butadiene derivatives as disclosed in US 4,356,429 and various heterocyclic optical brighteners as described in US 4,539,507. Benzazoles satisfying structural formula (G) are also useful electron transporting materials. Triazines are also known to be useful as electron transporting materials.

If both a hole-blocking layer and an electron-transporting layer 111 are used, electrons should pass readily from the electron-transporting layer 111 into the hole-blocking layer. Therefore, the electron affinity of the electron-transporting layer 111 should not greatly exceed that of the hole-blocking layer. Desirably, the electron affinity of the electron-transporting layer should be less than that of the hole-blocking layer or not exceed it by more than about 0.2 eV.

If an electron-transporting layer is used, its thickness may be between 2 and 100 nm and suitably between 5 and 20 nm.

15 Other Useful Organic Layers and Device Architecture

In some instances, layers 109 through 111 can optionally be collapsed into a single layer that serves the function of supporting both light emission and electron transportation. The hole-blocking layer, when present, and layer 111 may also be collapsed into a single layer that functions to block holes or excitons, and supports electron transport. It also known in the art that emitting materials may be included in the hole-transporting layer 107. In that case, the hole-transporting material may serve as a host. Multiple materials may be added to one or more layers in order to create a white-emitting OLED, for example, by combining blue- and yellow-emitting materials, cyan- and red-emitting materials, or red-, green-, and blue-emitting materials. White-emitting devices are described, for example, in EP 1 187 235, US 20020025419, EP 1 182 244, US 5,683,823, US 5,503,910, US 5,405,709, and US 5,283,182 and can be equipped with a suitable filter arrangement to produce a color emission.

This invention may be used in so-called stacked device architecture, for example, as taught in US 5,703,436 and US 6,337,492.

Deposition of Organic Layers

The organic materials mentioned above are suitably deposited by any means suitable for the form of the organic materials. In the case of small molecules, they are conveniently deposited through sublimation or evaporation, but can be deposited by other means such as coating from a solvent together with an optional binder to improve film formation. If the material is a polymer, solvent deposition is usually preferred. The material to be deposited by sublimation or evaporation can be vaporized from a sublimator "boat" often comprised of a tantalum material, e.g., as described in US 6,237,529, or can be first coated onto a donor sheet and then sublimed in closer proximity to the substrate. Layers with a mixture of materials can utilize separate sublimator boats or the materials can be pre-mixed and coated from a single boat or donor sheet. Patterned deposition can be achieved using shadow masks, integral shadow masks (US 5,294,870), spatially-defined thermal dye transfer from a donor sheet (US 5,688,551, US 5,851,709 and US 6,066,357) or an inkjet method (US 6,066,357).

Encapsulation

Most OLED devices are sensitive to moisture or oxygen, or both, so they are commonly sealed in an inert atmosphere such as nitrogen or argon, along with a desiccant such as alumina, bauxite, calcium sulfate, clays, silica gel, zeolites, alkaline metal oxides, alkaline earth metal oxides, sulfates, or metal halides and perchlorates. Methods for encapsulation and desiccation include, but are not limited to, those described in U.S. Patent No. 6,226,890. In addition, barrier layers such as SiO_x, Teflon, and alternating inorganic/polymeric layers are known in the art for encapsulation. Any of these methods of sealing or encapsulation and desiccation can be used with the EL devices constructed according to the present invention.

Optical Optimization

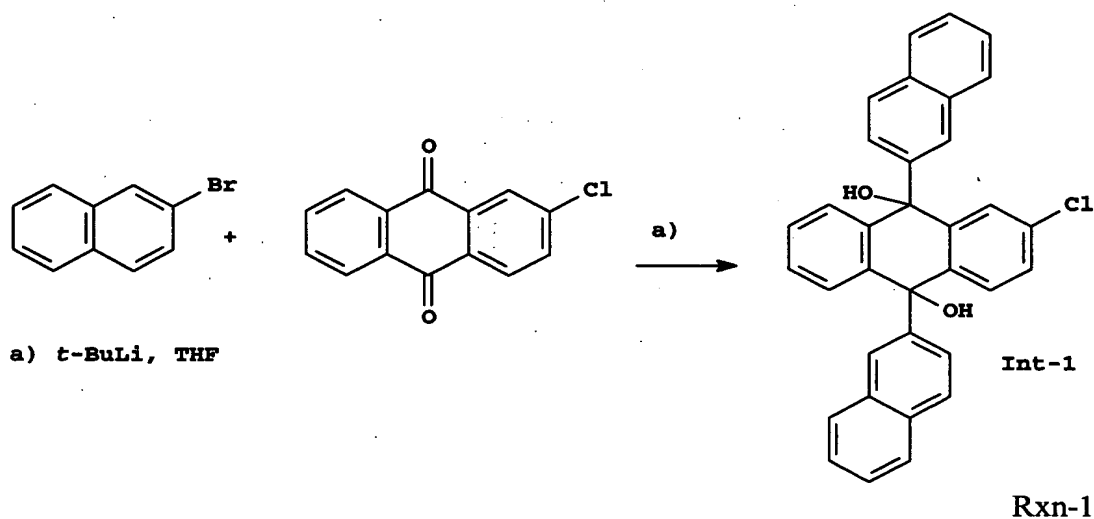
OLED devices of this invention can employ various well-known optical effects in order to enhance their emissive properties if desired. This includes optimizing layer thicknesses to yield maximum light transmission, providing dielectric mirror structures, replacing reflective electrodes with light-absorbing electrodes, providing anti-glare or anti-reflection coatings over the

display, providing a polarizing medium over the display, or providing colored, neutral density, or color-conversion filters over the display. Filters, polarizers, and anti-glare or anti-reflection coatings may be specifically provided over the EL device or as part of the EL device.

- 5 Embodiments of the invention may provide advantageous features such as higher luminous yield, lower drive voltage, higher power efficiency, improved stability, ease of manufacture, and reduced sublimation temperatures as well as desirable hues including those useful in the emission of white light (directly or through filters to provide multicolor displays). Embodiments of the
- 10 invention can also provide devices incorporating the EL device such as electronic displays and an area lighting devices.

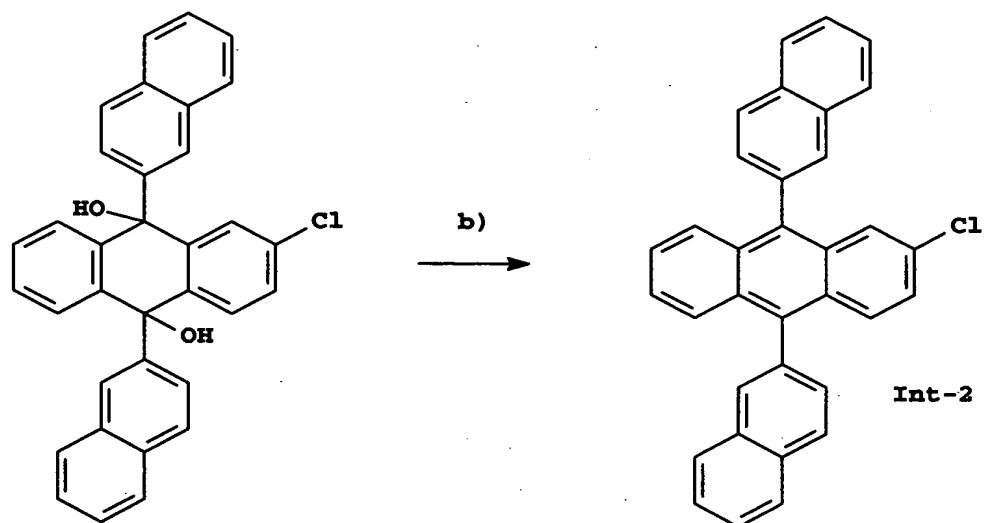
The invention and its advantages can be better appreciated by the following examples.

15 Synthetic Example: Preparation of Inv-1



- 20 Intermediate Int-1 was prepared by the following procedure (Rxn-1). 2-Bromonaphthalene (9.2 g, 44.4 mmol) was dissolved in dry THF (118 ml) and cooled to -78°C. *t*-BuLi (1.7 M, 52.3 g, 89 mmol) was added in dropwise manner over 5 min, then the reaction was stirred at this temperature for another 5 min. Upon the addition of 2-chloroanthraquinone (4.3 g, 17.8 mmol), the reaction

was removed from the acetone-dry ice bath and stirred at room temperature overnight. The reaction mixture was added to aqueous ammonium chloride solution and the product was extracted with methylene chloride. The organic phase was dried with magnesium sulfate, filtered, and concentrated. Purification
5 by crystallization (85% ether/ heptane) gave Int-1.

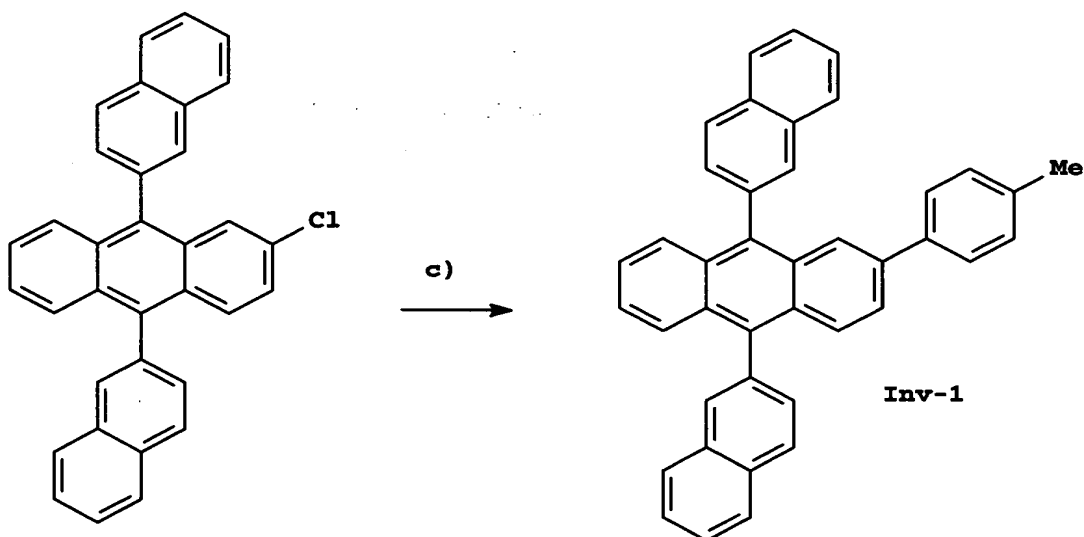


b) KI, NaH₂PO₂, AcOH

Rxn-2

Intermediate Int-2 was prepared by the following procedure (Rxn-
10 2). Potassium iodide (17.6 g, 106.02 mmol) and sodium hypophosphite hydrate (16.5 g, 188.1 mmol) were added to a mixture of Int-1 (5.7g, 11.4 mmol) in acetic acid (181 mL). The mixture was heated to reflux for 3 h, then cooled to room temperature. The yellow solid was filtered and washed with water and methanol to yield Int-2.

15



c) tris(dibenzylideneacetone)dipalladium(0),
 tricyclohexylphosphine, K_3PO_4 , Toluene

Rxn -3

Intermediate Inv-1 was prepared by the following procedure (Rxn-
 5 3). The 4-tolylboronic acid (1.2 eq.), tris(dibenzylideneacetone)dipalladium (0)
 (0.03 eq.), tricyclohexylphosphine (0.045 eq.), and potassium phosphate (2 eq.)
 were added to a mixture of Int-2 (1 eq.) in degassed toluene under dry conditions.
 The reaction mixture was heated to reflux overnight. The reaction mixture was
 cooled, filtered through celite, and added to water. The product was extracted
 10 from methylene chloride, dried with magnesium sulfate, filtered, and concentrated.
 Column chromatography (silica gel with 95% heptane/ methylene chloride eluent)
 yields Inv-1.

Device Example 1 – EL Device Fabrication of Samples 1-6

15 An EL device (Sample 1) satisfying the requirements of the
 invention was constructed in the following manner:

1. A glass substrate coated with an 85 nm layer of indium-tin oxide (ITO) as the anode was sequentially ultrasonicated in a commercial detergent, rinsed in deionized water,

degreased in toluene vapor and exposed to oxygen plasma for about 1 min.

2. Over the ITO was deposited a 1 nm fluorocarbon (CF_x) hole-injecting layer (HIL) by plasma-assisted deposition of CHF₃.
3. A hole-transporting layer (HTL) of *N,N'*-di-1-naphthyl-*N,N'*-diphenyl-4,4'-diaminobiphenyl (NPB) having a thickness of 75 nm was then evaporated from a tantalum boat.
4. A 20 nm light-emitting layer (LEL), including host material Inv-1 and light-emitting material TBP (2,5,8,11-tetra-*t*-butylperylene, 1.00 vol%), was then deposited onto the hole-transporting layer. These materials were also evaporated from tantalum boats.
5. A 35 nm electron-transporting layer (ETL) of tris(8-quinolinolato)aluminum (III) (AlQ₃) was then deposited onto the light-emitting layer. This material was also evaporated from a tantalum boat.
6. On top of the AlQ₃ layer was deposited a 220 nm cathode formed of a 10:1 volume ratio of Mg and Ag.

The above sequence completed the deposition of the EL device. The device was then hermetically packaged in a dry glove box for protection against ambient environment.

EL devices, Samples 2-5, incorporating Inv-1 were fabricated in an identical manner as Sample 1, except the amount of Inv-1 used (that is, the layer thickness of Inv-1) and the level of TBP are indicated in Table 1. Sample 6 was prepared in the same manner as Sample 1 except Inv-1 was replaced with TBADN, (2-*t*-butyl-9,10-di-(2-naphthyl)anthracene) and the TBP level was 1.50 vol%.

The devices thus formed were tested for efficiency and color at an operating current of 20 mA/cm² and the results are reported in Table 1 in the form

of output efficiency (W/A), luminance yield (cd/A), and CIE (Commission Internationale de L'Eclairage) coordinates. The devices were tested for stability by operating the cells at 20 mA/cm² for 250 h at 70 °C. The luminance after operating for this time relative to the initial luminance is listed in Table 1 as a percentage.

Table 1. Evaluation Results for EL devices 1-6.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	250 h Stability	Type
1	Inv-1	200	1.00	3.70	0.176	0.283	78%	Invention
2	Inv-1	400	1.00	4.18	0.184	0.333	77%	Invention
3	Inv-1	200	2.00	3.66	0.174	0.280	83%	Invention
4	Inv-1	400	2.00	3.89	0.180	0.328	81%	Invention
5	Inv-1	200	4.00	3.30	0.177	0.296	81%	Invention
6	TBADN	200	1.50	2.40	0.144	0.184	71%	Comparison

It can be seen from Table 1 that the anthracene material of the invention, Inv-1, affords a high luminance yield and very good operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-1/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 2 – EL Device Fabrication of Samples 7-12

EL devices, Samples 7-11, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-2. Sample 12 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6, except the devices were tested for stability by operating the cells at 20 mA/cm² for 200 h at 70 °C. The testing results are reported in Table 2.

Table 2. Evaluation Results for EL devices 7-12.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	200 h Stability	Type
7	Inv-2	200	1.00	3.35	0.164	0.264	86%	Invention
8	Inv-2	400	1.00	3.27	0.174	0.321	84%	Invention
9	Inv-2	200	2.00	2.88	0.165	0.257	89%	Invention
10	Inv-2	400	2.00	3.30	0.175	0.329	87%	Invention
11	Inv-2	200	4.00	1.71	0.311	0.538	80%	Invention
12	TBADN	200	1.50	2.86	0.144	0.217	83%	Comparison

It can be seen from Table 2 that the anthracene material of the invention, Inv-2, affords a good luminance yield and operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-2/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 3 – EL Device Fabrication of Samples 13-18

EL devices, Samples 7-11, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-3. Sample 18 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6, except the devices were tested for stability by operating the cells at 20 mA/cm² for 200 h at 70 °C. The testing results are reported in Table 3.

Table 3. Evaluation Results for EL devices 13-18.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	200 h Stability	Type
13	Inv-3	200	1.00	3.52	0.170	0.285	88%	Invention
14	Inv-3	400	1.00	4.26	0.174	0.328	87%	Invention
15	Inv-3	200	2.00	3.44	0.170	0.285	91%	Invention
16	Inv-3	400	2.00	4.14	0.175	0.335	89%	Invention
17	Inv-3	200	4.00	3.15	0.177	0.309	89%	Invention
18	TBADN	200	1.50	2.87	0.142	0.205	75%	Comparison

It can be seen from Table 3 that the anthracene material of the invention, Inv-3, affords a high luminance yield and very good operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-3/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 4 – EL Device Fabrication of Samples 19-24

EL devices, Samples 19-23, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-4. Sample 25 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6, except the devices were tested for stability by operating the cells at 20 mA/cm² for 200 h at 70 °C. The testing results are reported in Table 4.

Table 4. Evaluation Results for EL devices 19-24.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	200 h Stability	Type
19	Inv-4	200	1.00	3.51	0.172	0.270	72%	Invention
20	Inv-4	400	1.00	4.46	0.189	0.371	70%	Invention
21	Inv-4	200	2.00	3.47	0.173	0.277	75%	Invention
22	Inv-4	400	2.00	3.67	0.182	0.337	77%	Invention
23	Inv-4	200	4.00	3.46	0.176	0.312	75%	Invention
24	TBADN	200	1.50	2.47	0.144	0.184	74%	Comparison

It can be seen from Table 4 that the anthracene material of the invention, Inv-4, affords a high luminance yield and similar stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-4/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 5 – EL Device Fabrication of Samples 25-30.

EL devices, Samples 25-29, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-5. Sample 30 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6. The testing results are reported in Table 5.

Table 5. Evaluation Results for EL devices 25-30.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	250 h Stability	Type
25	Inv-5	200	1.00	3.43	0.161	0.250	86%	Invention
26	Inv-5	400	1.00	4.33	0.163	0.296	86%	Invention
27	Inv-5	200	2.00	3.40	0.160	0.254	88%	Invention
28	Inv-5	400	2.00	4.06	0.162	0.299	87%	Invention
29	Inv-5	200	4.00	3.15	0.165	0.275	86%	Invention
30	TBADN	200	1.50	2.85	0.141	0.191	79%	Comparison

It can be seen from Table 5 that the anthracene material of the invention, Inv-5, affords a high luminance yield and very good operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-5/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 6 – EL Device Fabrication of Samples 31-36

EL devices, Samples 31-35, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-7. Sample 36 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6, except the devices were tested for stability by operating the cells at 20 mA/cm² for 200 h at 70 °C. The testing results are reported in Table 6.

Table 6. Evaluation Results for EL devices 31-36.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	200 h Stability	Type
31	Inv-7	200	1.00	3.53	0.168	0.252	78%	Invention
32	Inv-7	400	1.00	3.96	0.176	0.319	76%	Invention
33	Inv-7	200	2.00	3.42	0.166	0.250	81%	Invention
34	Inv-7	400	2.00	3.71	0.171	0.310	78%	Invention
35	Inv-7	200	4.00	3.21	0.166	0.260	81%	Invention
36	TBADN	200	1.50	2.49	0.145	0.181	77%	Comparison

It can be seen from Table 6 that the anthracene material of the invention, Inv-7, affords a high luminance yield and similar or better operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-7/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 7 – EL Device Fabrication of Samples 37-42

EL devices, Samples 37-41, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-8. Sample 42 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6, except the devices were tested for stability by operating the cells at 20 mA/cm² for 200 h at 70 °C. The testing results are reported in Table 7.

Table 7. Evaluation Results for EL devices 37-42.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	200 h Stability	Type
37	Inv-8	200	1.00	3.24	0.161	0.239	83%	Invention
38	Inv-8	400	1.00	3.49	0.168	0.287	83%	Invention
39	Inv-8	200	2.00	3.49	0.157	0.252	86%	Invention
40	Inv-8	400	2.00	3.48	0.166	0.303	83%	Invention
41	Inv-8	200	4.00	2.36	0.178	0.283	85%	Invention
42	TBADN	200	1.50	2.85	0.141	0.189	76%	Comparison

It can be seen from Table 7 that the anthracene material of the invention, Inv-8, affords a high luminance yield and very good operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-8/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

Device Example 8 – EL Device Fabrication of Samples 43-48.

EL devices, Samples 43-47, were fabricated in an identical manner as Sample 1-5, except Inv-1 was replaced with Inv-9. Sample 48 was prepared in the same manner as Sample 6. The devices thus formed were tested for in the same manner as Samples 1-6. The testing results are reported in Table 8.

Table 8. Evaluation Results for EL devices 43-48.

Sample	Host	Host Level (nm)	TBP Level (vol%)	Yield (cd/A)	CIE _x	CIE _y	250 h Stability (%)	Type
43	Inv-9	200	1.00	3.63	0.186	0.317	65%	Invention
44	Inv-9	400	1.00	3.15	0.188	0.296	84%	Invention
45	Inv-9	200	2.00	3.38	0.182	0.308	86%	Invention
46	Inv-9	400	2.00	3.33	0.187	0.322	84%	Invention
47	Inv-9	200	4.00	2.73	0.195	0.320	84%	Invention
48	TBADN	200	1.50	2.57	0.144	0.189	71%	Comparison

It can be seen from Table 8 that the anthracene material of the invention, Inv-9, affords a high luminance yield and very good operating stability relative to a comparison anthracene material when the two materials are compared at similar levels. The Inv-9/TBP combination affords a color that is more blue-green than the TBADN/TBP combination and may be desirable for use in a white light-emitting device.

The entire contents of the patents and other publications referred to in this specification are incorporated herein by reference. The invention has been described in detail with particular reference to certain preferred embodiments thereof, but it will be understood that variations and modifications can be effected within the spirit and scope of the invention.

PARTS LIST

101	Substrate
103	Anode
105	Hole-Injecting layer (HIL)
107	Hole-Transporting layer (HTL)
109	Light-Emitting layer (LEL)
111	Electron-Transporting layer (ETL)
113	Cathode